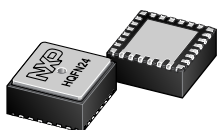


# NTM88Jxx5S

## Tire pressure monitor sensor

Rev. 2 — 6 June 2024

Preliminary data sheet



## 1 General description

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The NTM88 family consists of small (4 mm x 4 mm x 1.98 mm), fully integrated tire pressure monitoring sensors (TPMS). The devices described in this data sheet, NTM88Jxx5S, provide low transmitting power consumption, large customer memory size, and single- or dual-axis accelerometer architecture. The NTM88Jxx5S TPMS solution integrates an 8-bit microcontroller (MCU), pressure sensor, accelerometers in three ranges, programmable RF transmitter and flexible LF receiver. The sensor supports seven GPIOs, client SPI, and a 2-channel timer / pulse-width module.

## 2 Features and benefits

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- Optional pressure ranges<sup>1</sup>
- Optional accelerometer ranges: See [Section 3](#).
- Transducer measurement interfaces with low-power AFE:
  - 10-bit compensated pressure sense element
  - 10-bit compensated accelerometers
  - 8-bit compensated internal device temperature measurement
  - 8-bit compensated internal device voltage measurement
  - Two I/O pins can be used for external signals
- 8-bit S08 compact instruction set controller:
  - 64 bytes low-power “always on” NVM parameter registers
  - 512 bytes SRAM
  - 16 kB flash memory (512 bytes reserved for NXP coefficients)
  - Family of NXP firmware libraries available via royalty-free license
- Programmable RF transmitter
  - Characterized for RF carrier typical of 315 MHz or 434 MHz
  - Characterized for FSK in ~3 kHz increments or OOK modulation
  - Characterized for baud rate examples of 9.6 kbp/s, 19.2 kbp/s, and 38.4 kbp/s
- Flexible 125 kHz LF receiver:
  - Capability for ASK or OOK demodulation
  - Automated Manchester decoding
- Two channel timer / pulse-width module
- Client SPI to support host access to internal peripherals, registers, and memory
- Seven GPIOs with programmable multiplexing to support software development, external analog voltage input, timer, SPI, and wake-up
- Qualified in compliance with AEC-Q100, Rev. H

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<sup>1</sup> Consult NXP sales for details or specific requests.

- Long battery service life
- Internal temperature sensor
- Internal voltage sensor
- Six-channel, 8-, 10-, or 12-bit analog-to-digital converter with two external I/O inputs
- Internal 315 MHz/434 MHz RF transmitter
  - External crystal oscillator
  - PLL-based output with fractional-n divider
  - OOK and FSK modulation capability
  - Programmable data rate generator
  - Manchester, Bi-Phase, or NRZ data encoding
  - 256-bit RF data buffer variable length interrupt
  - Direct access to RF transmitter from MCU for unique formats
  - Low-power consumption
- Differential input LF detector/decoder on independent signal pins
- Real-time Interrupt driven by LFO with intervals of 2, 4, 8, 16, 32, 64, or 128 ms
- Free-running counter, low-power, wake up timer and periodic reset driven by LFO
- Watchdog timeout with selectable times and clock sources
- Two-channel general-purpose timer/PWM module (TPM1)
- Internal oscillators
  - MCU bus clock of 0.5, 1, 2, and 4 MHz (1, 2, 4, and 8 MHz HFO)
  - Low frequency, low-power time clock (LFO) with 1 ms period
  - Medium frequency, controller clock (MFO) of 8 µs period
- Low-voltage detection

3 Ordering information

Table 1. Ordering information

| Type number | Package |                                                                                                                                         |              |
|-------------|---------|-----------------------------------------------------------------------------------------------------------------------------------------|--------------|
|             | Name    | Description                                                                                                                             | Version      |
| NTM88Jxx5S  | HQFN24  | Plastic thermal enhanced quad flat package; no leads, 0.1 dimple wettable flank; 24 terminals; 0.5 mm pitch, 4 mm x 4 mm x 1.98 mm body | SOT1931-1(D) |

Table 2. Ordering options

| Part Number 'N8'            | Pressure Range 'p'     | Accelerometer 'aa' |      | X-axis Range     | Z-axis Range     | CodeH Hardware (First Rev) <sup>[1]</sup> |
|-----------------------------|------------------------|--------------------|------|------------------|------------------|-------------------------------------------|
| NTM88J125ST1 <sup>[2]</sup> | 90 kPa to 1110 kPa 'J' | XZ                 | '12' | –400 g to +400 g | –175 g to +550 g | \$8C                                      |
| NTM88J135ST1 <sup>[2]</sup> |                        |                    | '13' | –80 g to +90 g   | –360 g to +400 g | \$8D                                      |
| NTM88J145ST1 <sup>[2]</sup> |                        | XZ                 | 14   | –360 g to +400 g | –80 g to +90 g   | \$8E                                      |
| NTM88J155ST1 <sup>[2]</sup> |                        |                    | 15   | –360 g to +400 g | –360 g to +400g  | \$8F                                      |

[1] The value CodeF mentioned in the User Manual UM11227<sup>[1]</sup> depicts the version of firmware used by NXP during device tests, and will become \$FF as the device is shipped. The value of CodeF will be replaced again by the version number of the firmware library used by the customer at the time of device final application programming.

[2] Product under development, consult your NXP sales representatives for samples.

4 Block diagram

Figure 1 presents the device's main blocks and their signal interactions. Power management controls and bus control signals are not shown in this block diagram for clarity.

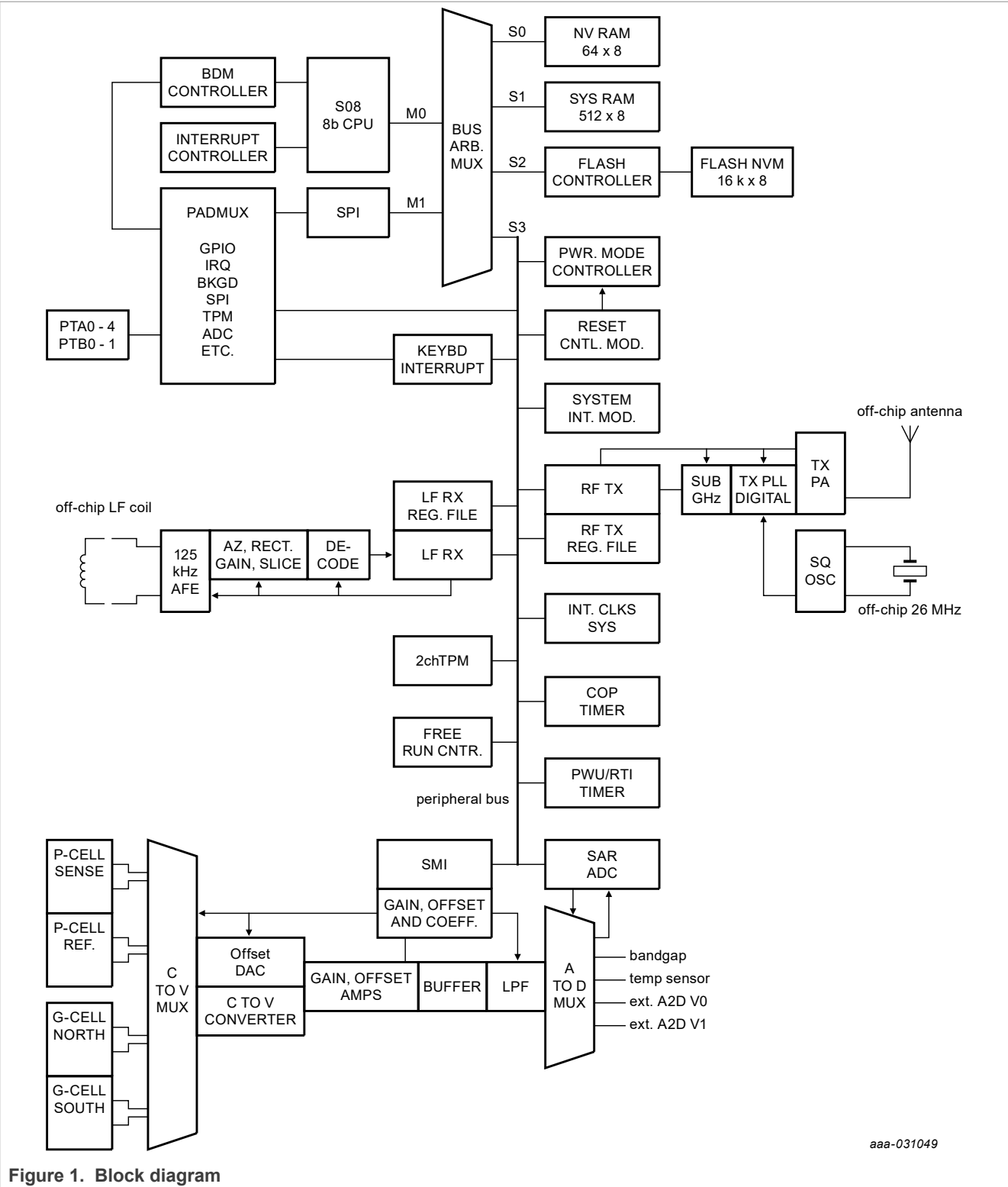
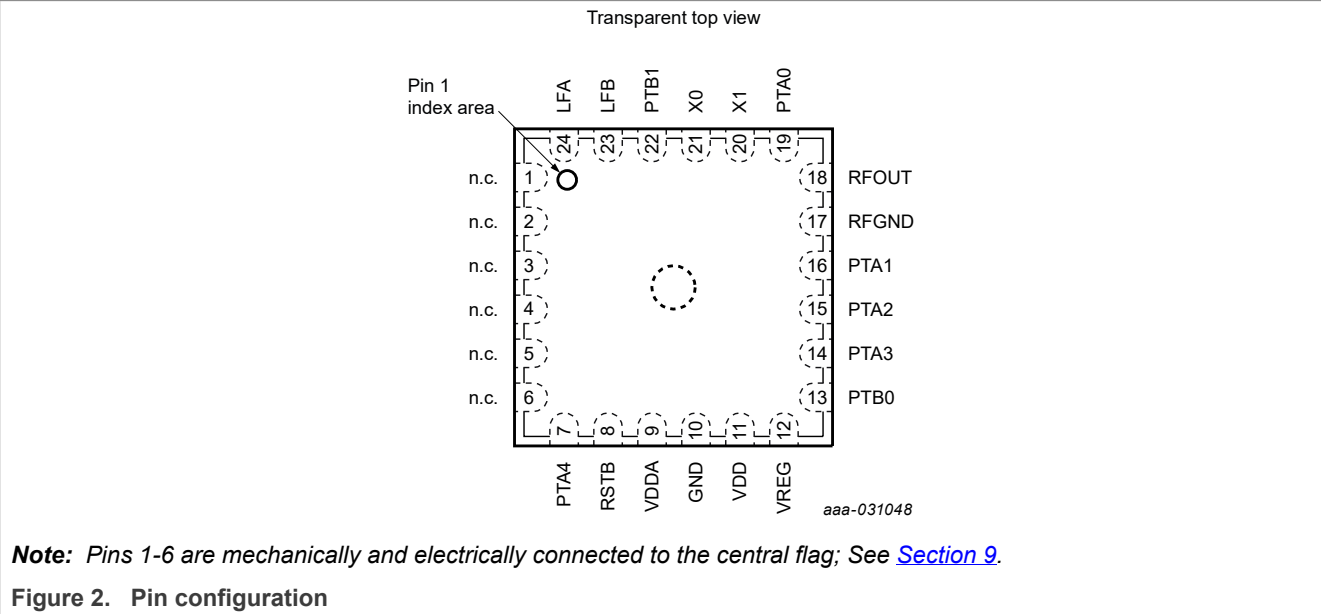


Figure 1. Block diagram

5 Pinning information

5.1 Pinning

A top view of the device pint with the pressure port on top is show in [Figure 2](#). The orientation of the internal Z-axis accelerometer is shown in [Figure 3](#).



5.2 Pin description

Table 3. Pin description

| Symbol | Pin | Function    | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
|--------|-----|-------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| n.c.   | 1   | —           | Do not connect electrical signals to this pin; solder joint only.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| n.c.   | 2   | —           | Do not connect electrical signals to this pin; solder joint only.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| n.c.   | 3   | —           | Do not connect electrical signals to this pin; solder joint only.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| n.c.   | 4   | —           | Do not connect electrical signals to this pin; solder joint only.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| n.c.   | 5   | —           | Do not connect electrical signals to this pin; solder joint only.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| n.c.   | 6   | —           | Do not connect electrical signals to this pin; solder joint only.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| PTA4   | 7   | PTA4 / BKGD | <p>PTA4 Pin - The PTA4 pin places the device in the BACKGROUND DEBUG mode (BDM) to evaluate MCU code and transfer data to/from the internal memory. If the BKGD/PTA4 pin is held low when the device comes out of a power-on-reset (POR), the device switches into the ACTIVE BACKGROUND DEBUG mode (BDM).</p> <p>The BKGD/PTA4 pin has an internal pullup device or can be connected to VDD in the application, unless there is a need to enter BDM operation after the device as been soldered into the PWB. If in-circuit BDM is desired, the BKGD/PTA4 pin should be connected to VDD through a resistor (~10 kΩ or greater) which can be over-driven by an external signal. This resistor reduces the possibility of inadvertently activating the debug mode in the application due to an EMC event.</p> <p>When the application programs port A to GPIOs, PTA4 becomes output-only.</p> |

Table 3. Pin description...continued

| Symbol | Pin | Function                  | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|--------|-----|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| RST_B  | 8   | Reset                     | <p>The RST_B pin is an active-low hardware reset. When asserted, the MCU takes the reset vector. It is also used to establish a BDM connection and for other test purposes.</p> <p>The RST_B pin has an internal pullup device and can be connected to VDD in the application unless there is a need to enter BDM operation after the device as been soldered to the PWB. If in-circuit BDM is desired, the RST_B pin can be left unconnected; but should be connected to VDD through a low impedance resistor (&lt;10 kΩ) which can be over-driven by an external signal. This low impedance resistor reduces the possibility of getting into the debug mode in the application due to an EMC event.</p> <p>Activation of the external reset function occurs when the voltage on the RST_B pin goes below <math>0.3 \times V_{DD}</math> for at least 100 ns before rising above <math>0.7 \times V_{DD}</math>.</p> |
| VDDA   | 9   | Analog supply             | <p>The analog circuits operate from a single power supply connected to the unit through the VDDA pin. VDDA is the positive supply and GND is the ground. The conductors to the power supply should be connected to the VDDA and GND pins and locally decoupled.</p> <p>Care should be taken to reduce measurement signal noise by separating the VDD, GND, VDDA, and RFGND pins using a "star" connection such that each metal trace does not share any load currents with other external devices.</p>                                                                                                                                                                                                                                                                                                                                                                                                                |
| GND    | 10  | Digital and analog ground | <p>The digital and analog circuits operate from a single power supply connected to the unit through the VDD, VDDA, and GND pins. GND is the ground. Care should be taken to reduce measurement signal noise by separating the GND and RFGND pins using a "star" connection such that each metal trace does not share any load currents with other external devices.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| VDD    | 11  | Digital supply            | <p>The digital circuits operate from a single power supply connected to the unit through the VDD and GND pins. VDD is the positive supply. The conductors to the power supply should be connected to the VDD and GND pins and locally decoupled.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| VREG   | 12  | 1.8 V regulation          | <p>The internal regulator for the RF analog circuits requires an external stabilization capacitor to GND.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| PTB0   | 13  | PTB0 / TPMCH0 / AD3       | <p>The PTB[0] pin is a general-purpose I/O pin. This pin can be configured as a nominal bidirectional I/O pin with programmable pullup devices. User software must configure the general-purpose I/O pin (PTB[1:0]) so that they do not result in "floating" inputs. PTB0 can be mapped to TPM channel 0, or to ADC channel 3.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| PTA3   | 14  | PTA3 / KBI3 / MOSI        | <p>The PTA[3] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in "floating" inputs. PTA[3] maps to keyboard interrupt function bit [3]. When SPI is enabled, PTA[3] serves as MOSI.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| PTA2   | 15  | PTA2 / KBI2 / MISO        | <p>The PTA[2] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in "floating" inputs. PTA[2] maps to keyboard interrupt function bit [2]. When SPI is enabled, PTA[2] serves as MISO.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| PTA1   | 16  | PTA1 / KBI1 / SCLK        | <p>The PTA[1] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |

Table 3. Pin description...continued

| Symbol | Pin | Function                 | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
|--------|-----|--------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|        |     |                          | “floating” inputs. PTA[1] maps to keyboard interrupt function bit [1]. When SPI is enabled, PTA[1] serves as SCLK                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
| RFGND  | 17  | RF ground                | Power in the RF output amplifier is returned to the supply through the RFGND pin. This conductor should be connected to the power supply using a “star” connection such that each metal trace does not share any load currents with other supply pins.                                                                                                                                                                                                                                                                                                                                                                                                          |
| RFOUT  | 18  | RF output                | The RFOUT pin is the RF energy data supplied by the unit to an external antenna.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| PTA0   | 19  | PTA0 / KBI0 / SS_B / IRQ | The PTA[0] pin is a general-purpose I/O pin. PTA[0] can be configured as a normal bidirectional I/O pin with programmable pullup or pulldown devices and/or wake-up interrupt capability. PTA[0] can be configured for external interrupt (IRQ). The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in “floating” inputs. PTA[0] maps to keyboard interrupt function bit [0]. When SPI is enabled, PTA0 serves as SS_B.                                                                                                            |
| X1     | 20  | RF crystal input         | The X1 pin is for an external 26 MHz crystal to be used by the internal PLL for creating the carrier frequencies and data rates for the RF pin.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| X0     | 21  | RF crystal output        | The X0 pin is for an external 26 MHz crystal to be used by the internal PLL for creating the carrier frequencies and data rates for the RF pin.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| PTB1   | 22  | PTB1 / TPMCH1 / AD4      | The PTB[1] pin is a general-purpose I/O pin. This pin can be configured as a nominal bidirectional I/O pin with programmable pullup devices. User software must configure the general-purpose I/O pins (PTB[1:0]) so that they do not result in “floating” inputs. PTB1 can be mapped to TPM channel 1, or to ADC channel 4.                                                                                                                                                                                                                                                                                                                                    |
| LFB    | 23  | LF input '-'             | <p>The LF[A:B] pins can be used by the LF receiver (LFR) as one differential input channel for sensing low-level signals from an external low frequency (LF) coil. The external LF coil should be connected between the LF[A] and the LF[B] pins.</p> <p>Signaling into the LFR pins can place the unit into various diagnostic or operational modes. The LFR is comprised of the detector and the decoder. Each LF[A:B] pin always has an impedance of approximately 500 kΩ to GND due to the LFR input circuitry.</p> <p>The LFA/LFB pins are used by the LFR when the LFEN control bit is set and are not functional when the LFEN control bit is clear.</p> |
| LFA    | 24  | LF input '+'             | <p>The LF[A:B] pins can be used by the LF receiver (LFR) as one differential input channel for sensing low-level signals from an external low frequency (LF) coil. The external LF coil should be connected between the LF[A] and the LF[B] pins.</p> <p>Signaling into the LFR pins can place the unit into various diagnostic or operational modes. The LFR is comprised of the detector and the decoder. Each LF[A:B] pin always has an impedance of approximately 500 kΩ to GND due to the LFR input circuitry.</p> <p>The LFA/LFB pins are used by the LFR when the LFEN control bit is set and are not functional when the LFEN control bit is clear.</p> |

5.3 Orientation

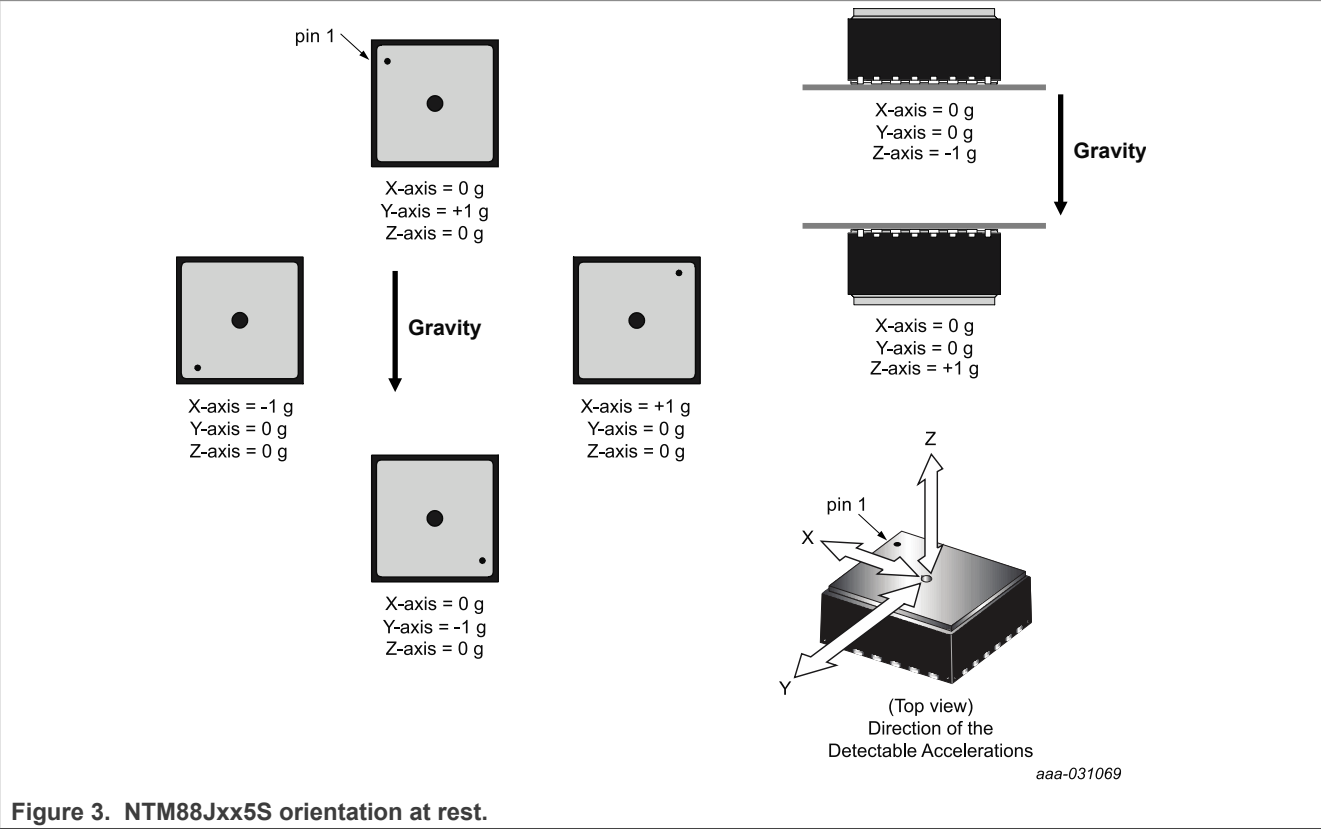


Figure 3. NTM88Jxx5S orientation at rest.

6 Electrical specifications

Tables in the electrical and mechanical specification sections of this data sheet may contain hyperlinked note references in the last cell of the row. The hyperlinks are linked to and defined in [Table 4](#).

Table 4. Electrical and mechanical specification note definition table

| Note identifier | Description                                             |
|-----------------|---------------------------------------------------------|
| A               | Parameters tested 100 % at final test.                  |
| B               | Parameters tested 100 % at unit probe.                  |
| C               | Verified by characterization, not tested in production. |
| D               | For information only, may be determined by simulation.  |

6.1 Maximum ratings (electrical)

Maximum ratings are the extreme limits the device can be exposed to without permanently damaging it. The device contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than the values shown in [Table 5](#). Keep  $V_{IN}$  and  $V_{OUT}$  within the range  $V_{SS} \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{DD}$ .

In all cases of transient environment, the sensor functional behaviors, parametric behaviors, and dimensions may deviate from the listed steady-state environment tolerances as compared to external reference(s).  $\tau$  is the characteristic thermal time constant, from device case ambient to the on-die temperature transducer. Transient

environment means less than  $2.3 \times \tau$  seconds since the last step-function transient of a condition; pressure, motion, temperature, supply voltage, electro-magnetic, humidity, vapor, media. Steady-state environment means  $2.3 \times \tau$  or more seconds of stable conditions; pressure, motion, temperature, supply voltage, electro-magnetic, humidity, vapor, media. Examples of step-function transient condition might be tire blow-out, drop impact, ice-bath submersion, battery connection 'bounce', nearby radio transmitter, and so forth.

Table 5. Maximum ratings

| Symbol             | Parameter                                                                                           | Conditions                                                                                        | Min                   | Typ | Max                   | Unit | Notes             |
|--------------------|-----------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------|-----------------------|-----|-----------------------|------|-------------------|
| V <sub>DD</sub>    | V <sub>DD</sub> or V <sub>DDA</sub> to V <sub>SS</sub>                                              | $T_L \leq T_A \leq T_H$                                                                           | -0.3                  | —   | 3.6                   | V    | <a href="#">C</a> |
| V <sub>IO</sub>    | IO pin current, each pin vs V <sub>DD</sub> / V <sub>DDA</sub> or V <sub>SS</sub>                   | $T_{AS} \text{ Min} \leq T_A \leq T_A \text{ Max}$                                                | V <sub>SS</sub> - 0.3 | —   | V <sub>DD</sub> + 0.3 | V    | <a href="#">C</a> |
| I <sub>IO</sub>    | IO pin current, pin vs V <sub>DD</sub> / V <sub>DDA</sub> or V <sub>SS</sub>                        | $T_L \leq T_A \leq T_H$ , V <sub>DDR</sub> Min $\leq$ V <sub>DD</sub> $\leq$ V <sub>DDR</sub> Max | -10                   | —   | 10                    | mA   | <a href="#">C</a> |
| I <sub>SUBIO</sub> | Substrate current injection, all IO pins except LFA LFB current from pin to V <sub>SS</sub> - 0.3 V | $T_L \leq T_A \leq T_H$ , V <sub>DDR</sub> Min $\leq$ V <sub>DD</sub> $\leq$ V <sub>DDR</sub> Max | —                     | 600 | —                     | μA   | <a href="#">C</a> |
| I <sub>SUBLF</sub> | Substrate current injection, LFA LFB current from pin to V <sub>SS</sub> - 0.3 V                    | $T_L \leq T_A \leq T_H$ , V <sub>DDF</sub> Min $\leq$ V <sub>DD</sub> $\leq$ V <sub>DDF</sub> Max | —                     | 2   | —                     | mA   | <a href="#">C</a> |
| I <sub>LATCH</sub> | Latch-up current, current to/from pin to V <sub>DD</sub> / V <sub>DDA</sub> + 0.3 V                 | $T_L \leq T_A \leq T_H$ , V <sub>DDR</sub> Min $\leq$ V <sub>DD</sub> $\leq$ V <sub>DDR</sub> Max | -100                  | —   | 100                   | mA   | <a href="#">C</a> |
| ESD <sub>HBM</sub> | Electrostatic discharge, human body model (HBM), all pins except RF, and LF                         | $T_A = 25^\circ\text{C}$ , V <sub>DD</sub> = 3.0 V                                                | -2000                 | —   | 2000                  | V    | <a href="#">C</a> |
| ESD <sub>HBM</sub> | Electrostatic discharge, human body model (HBM), RF, and LF                                         | $T_A = 25^\circ\text{C}$ , V <sub>DD</sub> = 3.0 V                                                | -2000                 | —   | 2000                  | V    | <a href="#">C</a> |
| ESD <sub>CDM</sub> | Electrostatic discharge, charged device model (CDM), all pins                                       | $T_A = 25^\circ\text{C}$ , V <sub>DD</sub> = 3.0 V                                                | -500                  | —   | 500                   | V    | <a href="#">C</a> |
| T <sub>STG</sub>   | Unpowered storage, temperature range                                                                | —                                                                                                 | -50                   | —   | 150                   | °C   | <a href="#">C</a> |

## 6.2 Operating conditions

The limits normally expected in the application that define the range of operation.

Table 6. Operating range

| Symbol           | Parameter                                                                                                                                          | Conditions                                                              | Min                | Typ | Max | Unit | Notes             |
|------------------|----------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------|--------------------|-----|-----|------|-------------------|
| V <sub>DDR</sub> | Operating voltage range, Parameter register retention where Min = V <sub>L</sub> , Typ = 3.0 V, Max = V <sub>H</sub>                               | $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$                   | 1.2                | 3.0 | 3.6 | V    | <a href="#">C</a> |
| V <sub>DDS</sub> | Operating voltage range, MCU and SW, Flash Read, RF TX, Voltage Measurement where Min = V <sub>L</sub> , Typ = 3.0 V, Max = V <sub>H</sub>         | $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$                   | V <sub>LVDRF</sub> | 3.0 | 3.6 | V    | <a href="#">C</a> |
| V <sub>DDM</sub> | Operating voltage range, Pressure, Temperature and Acceleration Measurements where Min = V <sub>L</sub> , Typ = 3.0 V, Max = V <sub>H</sub>        | $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$                   | 2.1                | 3.0 | 3.6 | V    | <a href="#">C</a> |
| V <sub>DDF</sub> | Operating voltage range, Flash Programming and LF RX, where Min = V <sub>L</sub> , Typ = 3.0 V, Max = V <sub>H</sub>                               | $-20^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$                      | 2.1                | 3.0 | 3.6 | V    | <a href="#">C</a> |
| T <sub>AS</sub>  | Operating temperature range, Full functionality except LF RX, and Flash Programming where Min = T <sub>L</sub> , Typ = 25 °C, Max = T <sub>H</sub> | V <sub>DDS</sub> Min $\leq$ V <sub>DD</sub> $\leq$ V <sub>DDS</sub> Max | -40                | 25  | 125 | °C   | <a href="#">C</a> |

Table 6. Operating range...continued

| Symbol                               | Parameter                                                                                                        | Conditions                                                                            | Min | Typ  | Max  | Unit | Notes             |
|--------------------------------------|------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|-----|------|------|------|-------------------|
| T <sub>AF</sub>                      | Operating temperature range, Operating voltage range, Full functionality, including LF RX, and Flash programming | V <sub>DDF</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDF</sub> Max                         | −20 | 25   | 85   | °C   | <a href="#">C</a> |
| T <sub>A-EXC</sub>                   | Operating temperature range excursion; 12 excursions of 15 minutes ea. (all Tolerances may be out of spec)       | V <sub>DDM</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDM</sub> Max                         | —   | —    | 150  | °C   | <a href="#">C</a> |
| I <sub>DD1</sub>                     | Supply Current; Stop1 Mode (only LFO, PWU, and param. reg. On)                                                   | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDR</sub> Min to Max | —   | 0.18 | 18   | μA   | <a href="#">B</a> |
| I <sub>DD4</sub>                     | Supply Current; Stop4 Mode (only MCU, RF, and LF disabled)                                                       | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDS</sub> Min to Max | —   | 75   | 125  | μA   | <a href="#">B</a> |
| I <sub>DDLFS</sub>                   | Supply Current; Standby LF sniff (and Stop1 equivalent)                                                          | Typ = 25 °C, 3.0 V, Max = T <sub>AF</sub><br>Min to Max & V <sub>DDF</sub> Min to Max | —   | 4.8  | 8.1  | μA   | <a href="#">C</a> |
| I <sub>DDLFD</sub>                   | Supply Current; Standby LF Decoding (and Stop1 equivalent)                                                       | Typ = 25 °C, 3.0 V, Max = T <sub>AF</sub><br>Min to Max & V <sub>DDF</sub> Min to Max | —   | 11.3 | 14.3 | μA   | <a href="#">C</a> |
| I <sub>DDR5K</sub>                   | Supply Current; MCU Run 500 kHz (and RF and LF disabled)                                                         | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDS</sub> Min to Max | —   | 0.8  | 1.0  | mA   | <a href="#">C</a> |
| I <sub>DDR1M</sub>                   | Supply Current; MCU Run 1 MHz (and RF and LF disabled)                                                           | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDS</sub> Min to Max | —   | 1.0  | 1.2  | mA   | <a href="#">C</a> |
| I <sub>DDR2M</sub>                   | Supply Current; MCU Run 2 MHz (and RF and LF disabled)                                                           | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDS</sub> Min to Max | —   | 1.42 | 1.6  | mA   | <a href="#">C</a> |
| I <sub>DDR4M</sub>                   | Supply Current; MCU Run 4 MHz (and RF and LF disabled)                                                           | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDS</sub> Min to Max | —   | 2.1  | 2.5  | mA   | <a href="#">B</a> |
| I <sub>DDRFT3</sub>                  | Supply Current; RF TX 5 dBm, 315 MHz (and Stop1 equivalent)                                                      | T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V                                       | —   | 5.7  | 6.1  | mA   | <a href="#">B</a> |
| I <sub>DDRFT4</sub>                  | Supply Current; RF TX 5 dBm, 434 MHz (and Stop1 equivalent)                                                      | T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V                                       | —   | 6.3  | 6.8  | mA   | <a href="#">B</a> |
| I <sub>DDRFTx1</sub>                 | Supply Current Increase w/ BOOST = 1 RF TX 5 dBm (and Stop1 equivalent)                                          | T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V                                       | —   | —    | 0.6  | mA   | <a href="#">C</a> |
| I <sub>DDIF0</sub>                   | Supply Current, RF Interframe period, IFPD = 0                                                                   | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDS</sub> Min to Max | —   | 610  | 870  | μA   | <a href="#">C</a> |
| I <sub>DDIF1</sub>                   | Supply Current, RF Interframe period, IFPD = 1                                                                   | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDS</sub> Min to Max | —   | 19   | 36   | μA   | <a href="#">C</a> |
| I <sub>DDA</sub> or I <sub>DDP</sub> | Supply Current Peak; Accel. or Pressure Measurements (and Stop4 equivalent)                                      | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDM</sub> Min to Max | —   | 2.8  | 3.15 | mA   | <a href="#">C</a> |
| I <sub>DDV</sub> or I <sub>DDT</sub> | Supply Current Peak; Voltage or Temp. Measurements (and Stop4 equivalent)                                        | Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub><br>Min to Max & V <sub>DDM</sub> Min to Max | —   | 2.8  | 3.8  | mA   | <a href="#">C</a> |

## 6.3 Charge consumptions

**Table 7. Charge consumptions**

$T_L \leq T_A \leq T_H$ , unless otherwise specified.

| Symbol        | Parameter                                                                          | Conditions                                 | Min | Typ  | Max | Unit         | Notes             |
|---------------|------------------------------------------------------------------------------------|--------------------------------------------|-----|------|-----|--------------|-------------------|
| $Q_{wake}$    | Stop1 to run charge consumption, $F_{bus}$ set for 4 MHz                           | $V_{DDM} Min \leq V_{DD} \leq V_{DDM} Max$ | —   | 0.10 | —   | $\mu A$ -sec | <a href="#">C</a> |
| $QPA_{r512}$  | Pressure or accelerometer charge consumption; Raw 512 $\mu s$ settling per sample  | $V_{DDM} Min \leq V_{DD} \leq V_{DDM} Max$ | —   | 0.95 | —   | $\mu A$ -sec | <a href="#">C</a> |
| $QPA_{r2048}$ | Pressure or accelerometer charge consumption; Raw 2048 $\mu s$ settling per sample | $V_{DDM} Min \leq V_{DD} \leq V_{DDM} Max$ | —   | 1.85 | —   | $\mu A$ -sec | <a href="#">C</a> |
| $QP_{c3}$     | Pressure charge consumption; Compensation third order per sample                   | $V_{DDM} Min \leq V_{DD} \leq V_{DDM} Max$ | —   | 1.77 | —   | $\mu A$ -sec | <a href="#">D</a> |
| $QA_{c2}$     | Accelerometer charge consumption; Compensation second order per sample             | $V_{DDM} Min \leq V_{DD} \leq V_{DDM} Max$ | —   | 1.95 | —   | $\mu A$ -sec | <a href="#">D</a> |
| $QVT_{r50}$   | Voltage or temperature charge consumption; Raw 50 $\mu s$ conversion per sample    | $V_{DDM} Min \leq V_{DD} \leq V_{DDM} Max$ | —   | 0.2  | —   | $\mu A$ -sec | <a href="#">C</a> |
| $QVT_{c250}$  | Voltage or temperature charge consumption; Compensation ~0.25 ms per sample        | $V_{DDM} Min \leq V_{DD} \leq V_{DDM} Max$ | —   | 0.50 | —   | $\mu A$ -sec | <a href="#">D</a> |

## 6.4 Clocks and thresholds

**Table 8. Clocks and thresholds**

$V_{DDS} Min \leq V_{DD} \leq V_{DDS} Max$ ,  $T_{AS} Min \leq T_A \leq T_{AS} Max$ , unless otherwise specified.

| Symbol      | Parameter                                  | Conditions                                       | Min  | Typ | Max  | Unit    | Notes             |
|-------------|--------------------------------------------|--------------------------------------------------|------|-----|------|---------|-------------------|
| $f_{BUS}$   | MCU bus frequency multiple of HFO          | $V_{DD} > V_{LVDRF}$                             | —    | 0.5 | —    | x HFO   | <a href="#">D</a> |
| $f_{HFO}$   | High frequency oscillator, multiple of MFO | $V_{DD} > V_{LVDRF}$                             | —    | 64  | —    | x MFO   | <a href="#">D</a> |
| $t_{HFOST}$ | Stabilization time                         | —                                                | —    | 300 | 1000 | $\mu s$ | <a href="#">D</a> |
| $f_{MFO}$   | Medium frequency oscillator                | $V_{DD} > V_{LVDRF}$                             | 107  | 125 | 135  | kHz     | <a href="#">A</a> |
| $f_{LFO}$   | Low frequency oscillator                   | —                                                | 504  | —   | 1512 | Hz      | <a href="#">B</a> |
| $f_{LFRO}$  | LFR Clock (derived from LFRO)              | —                                                | 120  | 129 | 139  | kHz     | <a href="#">B</a> |
| $t_{STOP1}$ | MCU wake-up time                           | From Stop1 to 1 <sup>st</sup> instruction, 4 MHz | —    | 50  | 70   | $\mu s$ | <a href="#">C</a> |
| $t_{STOP4}$ | MCU wake-up time                           | From Stop4 to 1 <sup>st</sup> instruction, 4 MHz | —    | 25  | 35   | $\mu s$ | <a href="#">C</a> |
| $t_{LV}$    | Low voltage times                          | $V_{DD} < V_{LVx}$                               | —    | —   | 10   | $\mu s$ | <a href="#">D</a> |
| $V_{LVWLF}$ | Low voltage warning (LVW)                  | Lower threshold, $V_{DD}$ falling                | 1.95 | —   | 2.2  | V       | <a href="#">C</a> |
| $V_{LVWLR}$ | Low voltage warning (LVW)                  | Lower threshold, $V_{DD}$ rising                 | 2.02 | —   | 2.1  | V       | <a href="#">C</a> |
| $V_{LVWHF}$ | Low voltage warning (LVW)                  | Higher threshold, $V_{DD}$ falling               | 2.28 | —   | 2.54 | V       | <a href="#">C</a> |
| $V_{LVWHR}$ | Low voltage warning (LVW)                  | Higher threshold, $V_{DD}$ rising                | 2.34 | —   | 2.61 | V       | <a href="#">C</a> |
| $V_{LVDLF}$ | Low voltage detection (LVD)                | Lower threshold, $V_{DD}$ falling                | 1.79 | —   | 1.96 | V       | <a href="#">C</a> |
| $V_{LVDLR}$ | Low voltage detection (LVD)                | Lower threshold, $V_{DD}$ rising                 | 1.87 | —   | 2.03 | V       | <a href="#">C</a> |

Table 8. Clocks and thresholds...continued

 $V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

| Symbol             | Parameter                   | Conditions                                | Min  | Typ | Max | Unit | Notes             |
|--------------------|-----------------------------|-------------------------------------------|------|-----|-----|------|-------------------|
| V <sub>LVDHF</sub> | Low voltage detection (LVD) | Higher threshold, V <sub>DD</sub> falling | 1.95 | —   | 2.2 | V    | <a href="#">C</a> |
| V <sub>LVDHR</sub> | Low voltage detection (LVD) | Higher threshold, V <sub>DD</sub> rising  | 2.02 | —   | 2.1 | V    | <a href="#">C</a> |
| V <sub>LVDRF</sub> | RF LVD                      | V <sub>DD</sub> falling                   | 1.6  | —   | 2.1 | V    | <a href="#">C</a> |
| T <sub>FDR</sub>   | Flash memory data retention | —                                         | 10   | —   | —   | Yr   | <a href="#">D</a> |

## 6.5 Power-on reset operation

When power is initially applied to the device, or when the supply voltage drops below the V<sub>POR</sub> level, the POR circuit causes a reset condition. As the supply voltage rises, the LVD circuit holds the chip in reset until the supply has risen above the level determined by LVDV bit. Both the POR bit and the LVD bit in SRS are set following a POR.

Table 9. Power-on reset

 $V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

| Symbol            | Parameter            | Conditions                                     | Min | Typ | Max | Unit | Notes             |
|-------------------|----------------------|------------------------------------------------|-----|-----|-----|------|-------------------|
| t <sub>R</sub>    | Power on reset (POR) | V <sub>DD</sub> risetime to avoid latch up     | —   | —   | 1   | s    | <a href="#">C</a> |
| t <sub>POR</sub>  | Power on reset (POR) | Time for V <sub>DD</sub> < 0.5 V to assure POR | 70  | —   | —   | μs   | <a href="#">C</a> |
| V <sub>PORR</sub> | Power on reset (POR) | Rising voltage to release reset                | —   | —   | 2.1 | V    | <a href="#">C</a> |
| V <sub>PORA</sub> | Power on reset (POR) | Falling voltage to assert reset                | 0.8 | —   | —   | V    | <a href="#">C</a> |

## 6.6 GPIO port pins

Table 10. GPIO port pins

 $V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

| Symbol             | Parameter                  | Conditions                                                                                  | Min                                       | Typ | Max                                       | Unit | Notes             |
|--------------------|----------------------------|---------------------------------------------------------------------------------------------|-------------------------------------------|-----|-------------------------------------------|------|-------------------|
| V <sub>OH</sub>    | Output high voltage        | I <sub>LOAD</sub> = 5 mA                                                                    | V <sub>DD</sub> – 0.35                    | —   | —                                         | V    | <a href="#">D</a> |
| V <sub>OL</sub>    | Output low voltage         | I <sub>LOAD</sub> = 5 mA                                                                    | —                                         | —   | V <sub>SS</sub> + 0.35                    | V    | <a href="#">D</a> |
| V <sub>IHn</sub>   | Input high voltage         | 2.3 V ≤ V <sub>DD</sub> ≤ V <sub>H</sub> , T <sub>A</sub> = T <sub>L</sub> , T <sub>H</sub> | 0.7 × V <sub>DD</sub> / V <sub>DDA</sub>  | —   | V <sub>DD</sub> / V <sub>DDA</sub>        | V    | <a href="#">D</a> |
| V <sub>IHv</sub>   | Input high voltage         | V <sub>DD</sub> ≤ 2.3 V, T <sub>A</sub> = 25 °C                                             | 0.85 × V <sub>DD</sub> / V <sub>DDA</sub> | —   | V <sub>DD</sub> / V <sub>DDA</sub>        | V    | <a href="#">D</a> |
| V <sub>ILn</sub>   | Input low voltage          | 2.3 V ≤ V <sub>DD</sub> ≤ V <sub>H</sub> , T <sub>A</sub> = T <sub>L</sub> , T <sub>H</sub> | V <sub>SS</sub>                           | —   | 0.35 × V <sub>DD</sub> / V <sub>DDA</sub> | V    | <a href="#">D</a> |
| V <sub>ILv</sub>   | Input low voltage          | V <sub>DD</sub> ≤ 2.3 V, T <sub>A</sub> = 25 °C                                             | V <sub>SS</sub>                           | —   | 0.28 × V <sub>DD</sub> / V <sub>DDA</sub> | V    | <a href="#">D</a> |
| I <sub>IH</sub>    | Input high current, PTA0:3 | Pulldown disabled; V <sub>IH</sub> Min                                                      | –1                                        | —   | +1                                        | μA   | <a href="#">D</a> |
| I <sub>IHp</sub>   | Input high current, PTA0:3 | Pulldown enabled; V <sub>IH</sub> Min                                                       | 0                                         | —   | 120                                       | μA   | <a href="#">D</a> |
| I <sub>IL</sub>    | Input low current, PTA0:3  | Pullup disabled; V <sub>IL</sub> Max                                                        | –1                                        | —   | +1                                        | μA   | <a href="#">D</a> |
| I <sub>ILp</sub>   | Input low current, PTA0:3  | Pullup enabled; V <sub>IL</sub> Max                                                         | –120                                      | —   | 0                                         | μA   | <a href="#">D</a> |
| I <sub>IH-IL</sub> | Input current PTA4 only    | V <sub>IH</sub> Min and V <sub>IL</sub> Max                                                 | –120                                      | —   | 120                                       | μA   | <a href="#">D</a> |

Table 10. GPIO port pins...continued

$V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

| Symbol     | Parameter             | Conditions               | Min | Typ | Max | Unit | Notes             |
|------------|-----------------------|--------------------------|-----|-----|-----|------|-------------------|
| $C_{IO}$   | Pin capacitance       | $V_{DD} = 3.0 \text{ V}$ | 0   | —   | 15  | pF   | <a href="#">D</a> |
| $C_{MISO}$ | MISO load capacitance | $V_{DD} = 3.0 \text{ V}$ | —   | —   | 50  | pF   | <a href="#">D</a> |

## 6.7 SPI timing characteristics

Table 11. SPI timing

$V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

| Symbol          | Parameter                                        | Conditions | Min | Typ | Max | Unit             | Notes             |
|-----------------|--------------------------------------------------|------------|-----|-----|-----|------------------|-------------------|
| $t_{SSMIN}$     | SS_B asserted period                             | —          | 1   | —   | —   | $f_{BUS}$ period | <a href="#">D</a> |
| $t_{ACCESS}$    | SS_B low to MISO                                 | —          | —   | —   | 50  | ns               | <a href="#">D</a> |
| $t_{LEAD}$      | SS_B low to SCLK start                           | —          | 50  | —   | —   | ns               | <a href="#">D</a> |
| $t_{SETUP}$     | MOSI to SCLK start                               | —          | 20  | —   | —   | ns               | <a href="#">D</a> |
| $t_{SCLK}$      | SCLK period                                      | —          | 100 | —   | —   | ns               | <a href="#">D</a> |
| $t_{SCLKH}$     | SCLK high portion                                | —          | 35  | —   | —   | ns               | <a href="#">D</a> |
| $t_{SCLKL}$     | SCLK low portion                                 | —          | 35  | —   | —   | ns               | <a href="#">D</a> |
| $t_{SCLKR}$     | SCLK risetime                                    | —          | —   | 10  | 25  | ns               | <a href="#">D</a> |
| $t_{SCLKF}$     | SCLK fall time                                   | —          | —   | 10  | 25  | ns               | <a href="#">D</a> |
| $t_{VALID}$     | MISO valid transition time                       | —          | —   | —   | 30  | ns               | <a href="#">D</a> |
| $t_{HOLD\_IN}$  | MOSI hold time                                   | —          | 10  | —   | —   | ns               | <a href="#">D</a> |
| $t_{HOLD\_OUT}$ | SCLK high to MISO transition start               | —          | 0   | —   | —   | ns               | <a href="#">D</a> |
| $t_{LAG}$       | Final SCLK low to SS_B high                      | —          | 60  | —   | —   | ns               | <a href="#">D</a> |
| $t_{DISABLE}$   | SS_B high to MISO 3-state                        | —          | —   | —   | 60  | ns               | <a href="#">D</a> |
| $t_{SS\_REJ}$   | SS_B noise rejection period                      | —          | —   | —   | 5   | ns               | <a href="#">D</a> |
| $t_{SSCLK}$     | SS_B high to SCLK high                           | —          | 50  | —   | —   | ns               | <a href="#">D</a> |
| $t_{CLKSS}$     | SCLK high to SCLK low                            | —          | 50  | —   | —   | ns               | <a href="#">D</a> |
| $t_{SSN}$       | SS_B not asserted period                         | —          | 6   | —   | —   | $f_{BUS}$ period | <a href="#">D</a> |
| $t_{LEAD\_WU}$  | Wake-up by SS_B low to SCLK start                | —          | 1   | —   | —   | ms               | <a href="#">D</a> |
| $t_{SPI\_EN}$   | SPI enable by SS_B low after $V_{DD} > V_{PORR}$ | —          | 200 | —   | —   | $\mu\text{s}$    | <a href="#">D</a> |

## 6.8 Temperature measurement characteristics

Table 12. Temperature measurement

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer function:  $T^{\circ}\text{C} = (1^{\circ}\text{C} / \text{LSB} \times T_{CODE}) - 55^{\circ}\text{C}$

| Symbol         | Parameter   | Conditions | Min  | Typ | Max  | Unit                            | Notes             |
|----------------|-------------|------------|------|-----|------|---------------------------------|-------------------|
| $DT_{MAX-MIN}$ | Sensitivity | —          | 0.93 | 1   | 1.08 | $^{\circ}\text{C} / \text{LSB}$ | <a href="#">C</a> |
| $T_{ERROR}$    | Error       | —          | —    | 0   | —    | LSB                             | <a href="#">C</a> |
| $T_{UNDER}$    | Underflow   | —          | —    | 1   | —    | LSB                             | <a href="#">C</a> |

**Table 12. Temperature measurement...continued**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer function:  $T \text{ } ^\circ\text{C} = (1 \text{ } ^\circ\text{C} / \text{LSB} \times T_{\text{CODE}}) - 55 \text{ } ^\circ\text{C}$

| Symbol                | Parameter                     | Conditions                             | Min | Typ | Max | Unit | Notes             |
|-----------------------|-------------------------------|----------------------------------------|-----|-----|-----|------|-------------------|
| T <sub>OVER</sub>     | Overflow                      | —                                      | —   | 255 | —   | LSB  | <a href="#">C</a> |
| T <sub>MIN</sub>      | Temperature measurement       | T <sub>A</sub> = -50 °C                | —   | 5   | —   | LSB  | <a href="#">D</a> |
| T <sub>RATE-MIN</sub> | Temperature measurement       | T <sub>A</sub> = -40 °C                | 11  | 15  | 19  | LSB  | <a href="#">C</a> |
| T <sub>CODE</sub>     | Temperature measurement       | T <sub>A</sub> = -20 °C                | 32  | 35  | 38  | LSB  | <a href="#">A</a> |
| T <sub>CODE</sub>     | Temperature measurement       | T <sub>A</sub> = 0 °C                  | 52  | 55  | 58  | LSB  | <a href="#">C</a> |
| T <sub>CODE</sub>     | Temperature measurement       | T <sub>A</sub> = 25 °C                 | 77  | 80  | 83  | LSB  | <a href="#">B</a> |
| T <sub>CODE</sub>     | Temperature measurement       | T <sub>A</sub> = 70 °C                 | 122 | 125 | 128 | LSB  | <a href="#">C</a> |
| T <sub>CODE</sub>     | Temperature measurement       | T <sub>A</sub> = 85 °C                 | 137 | 140 | 143 | LSB  | <a href="#">A</a> |
| T <sub>CODE</sub>     | Temperature measurement       | T <sub>A</sub> = 105 °C                | 156 | 160 | 164 | LSB  | <a href="#">C</a> |
| T <sub>RATE-MAX</sub> | Temperature measurement       | T <sub>A</sub> = 125 °C                | 175 | 180 | 185 | LSB  | <a href="#">B</a> |
| T <sub>MAX</sub>      | Temperature measurement       | T <sub>A</sub> = 150 °C <sup>[1]</sup> | —   | 205 | —   | LSB  | <a href="#">D</a> |
| T <sub>DRIFT</sub>    | Temperature measurement drift | —                                      | -3  | —   | +3  | LSB  | <a href="#">C</a> |

[1] Temperature excursions, time at T<sub>MAX</sub> must not exceed 12 events of 15 minutes duration during the product lifetime.

## 6.9 Voltage measurement characteristics

**Table 13. Voltage measurement characteristics**

$V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer function:  $V = (0.01 \text{ V} / \text{LSB} \times V_{\text{CODE}}) + 1.22 \text{ V}$

Interpolated limits between -40 °C to 0 °C and between 50 °C to 125 °C.

| Symbol                | Parameter                      | Conditions                                                                                 | Min | Typ | Max | Unit     | Notes             |
|-----------------------|--------------------------------|--------------------------------------------------------------------------------------------|-----|-----|-----|----------|-------------------|
| DV <sub>MAX-MIN</sub> | Sensitivity                    | —                                                                                          | 9   | 10  | 12  | mV / LSB | <a href="#">C</a> |
| V <sub>ERROR</sub>    | Error                          | —                                                                                          | —   | 0   | —   | LSB      | <a href="#">C</a> |
| V <sub>UNDER</sub>    | Underflow                      | —                                                                                          | —   | 1   | —   | LSB      | <a href="#">C</a> |
| V <sub>OVER</sub>     | Overflow                       | —                                                                                          | —   | 255 | —   | LSB      | <a href="#">C</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 2.8 V | 0 °C ≤ T <sub>A</sub> ≤ 50 °C, V <sub>DD</sub> = 2.8 V                                     | 153 | 158 | 163 | LSB      | <a href="#">C</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 3.0 V | 0 °C ≤ T <sub>A</sub> ≤ 50 °C, V <sub>DD</sub> = 3.0 V                                     | 173 | 178 | 183 | LSB      | <a href="#">C</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 3.3 V | 0 °C ≤ T <sub>A</sub> ≤ 50 °C, V <sub>DD</sub> = 3.3 V                                     | 203 | 208 | 213 | LSB      | <a href="#">C</a> |
| V <sub>MIN</sub>      | V <sub>DD</sub> voltage, 1.8 V | —                                                                                          | 38  | 58  | 78  | LSB      | <a href="#">C</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 2.1 V | —                                                                                          | 68  | 88  | 108 | LSB      | <a href="#">B</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 2.3 V | -40 °C ≤ T <sub>A</sub> ≤ 0 °C or 50 °C ≤ T <sub>A</sub> ≤ 125 °C, V <sub>DD</sub> = 2.3 V | 98  | 108 | 118 | LSB      | <a href="#">C</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 2.8 V | -40 °C ≤ T <sub>A</sub> ≤ 0 °C or 50 °C ≤ T <sub>A</sub> ≤ 125 °C, V <sub>DD</sub> = 2.8 V | 148 | 158 | 168 | LSB      | <a href="#">C</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 3.0 V | -40 °C ≤ T <sub>A</sub> ≤ 0 °C or 50 °C ≤ T <sub>A</sub> ≤ 125 °C, V <sub>DD</sub> = 3.0 V | 168 | 178 | 188 | LSB      | <a href="#">B</a> |
| V <sub>CODE</sub>     | V <sub>DD</sub> voltage, 3.3 V | -40 °C ≤ T <sub>A</sub> ≤ 0 °C or 50 °C ≤ T <sub>A</sub> ≤ 125 °C, V <sub>DD</sub> = 3.3 V | 198 | 208 | 218 | LSB      | <a href="#">C</a> |
| V <sub>MAX</sub>      | V <sub>DD</sub> voltage, 3.6 V | —                                                                                          | 228 | 238 | 248 | LSB      | <a href="#">C</a> |
| V <sub>DRIFT</sub>    | Voltage drift                  | —                                                                                          | -3  | —   | +3  | LSB      | <a href="#">C</a> |

**Table 14. External pin voltage measurement**

$V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer function:  $V = (V_{DD} \text{ V} / \text{LSB} \times \text{GxCODE}) / 1023$ , where  $x = 0$  for PTB0, 1 for PTB1

| Symbol                    | Parameter                                   | Conditions    | Min | Typ             | Max | Unit    | Notes             |
|---------------------------|---------------------------------------------|---------------|-----|-----------------|-----|---------|-------------------|
| $\Delta \text{GxMAX-MIN}$ | Sensitivity                                 | —             | —   | $V_{DD} / 1023$ | —   | V / LSB | <a href="#">C</a> |
| GxERROR                   | Error                                       | Status = \$01 | —   | 0               | —   | LSB     | <a href="#">C</a> |
| GxCODE                    | Voltage measurement, $V = 0 \text{ V}$      | Status = \$00 | —   | 0               | —   | LSB     | <a href="#">C</a> |
| GxCODE                    | Voltage measurement, $V = V_{DD} \text{ V}$ | —             | —   | 1023            | —   | LSB     | <a href="#">C</a> |
| GxDRIFFT                  | Voltage measurement drift                   | —             | −1  | —               | +1  | LSB     | <a href="#">C</a> |

## 6.10 Pressure measurement characteristics

Unless otherwise noted, stated tolerances are valid only with Initial Sample Delay [ISD3:0] set for > 2.5 ms and MCU placed in STOP4 mode.

### 6.10.1 Pressure measurement characteristic (90 kPa to 1110 kPa) range

**Table 15. Pressure measurement characteristics (90 kPa to 1110 kPa) range**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer function:  $P \text{ kPa} = (1.0 \text{ kPa} / \text{LSB} \times P_{\text{CODE}}) + 88.0 \text{ kPa}$

Interpolated limits between 105 °C and 125 °C.

| Symbol                      | Parameter                | Conditions                       | Min  | Typ  | Max  | Unit    | Notes             |
|-----------------------------|--------------------------|----------------------------------|------|------|------|---------|-------------------|
| $\Delta P_{\text{MAX-Min}}$ | Sensitivity              | —                                | 0.98 | 1.0  | 1.02 | kPa/LSB | <a href="#">C</a> |
| P <sub>ERROR</sub>          | Error                    | —                                | —    | 0    | —    | LSB     | <a href="#">C</a> |
| P <sub>UNDER</sub>          | Underflow                | FW error status bit 0 = 1        | —    | 1    | —    | LSB     | <a href="#">C</a> |
| P <sub>OVER</sub>           | Overflow                 | FW error status bit 0 = 1        | —    | 1023 | —    | LSB     | <a href="#">C</a> |
| P <sub>MIN</sub>            | Proof pressure, 90 kPa   | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | —    | 2    | 14   | LSB     | <a href="#">D</a> |
| P <sub>CODE</sub>           | Proof pressure, 100 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 7    | 12   | 17   | LSB     | <a href="#">A</a> |
| P <sub>CODE</sub>           | Proof pressure, 260 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 167  | 172  | 177  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 300 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 207  | 212  | 217  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 430 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 337  | 342  | 347  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 600 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 507  | 512  | 517  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 770 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 677  | 682  | 687  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 800 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 707  | 712  | 717  | LSB     | <a href="#">A</a> |
| P <sub>CODE</sub>           | Proof pressure, 940 kPa  | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 847  | 852  | 857  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 1050 kPa | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 957  | 962  | 967  | LSB     | <a href="#">A</a> |
| P <sub>MAX</sub>            | Proof pressure, 1110 kPa | −40 °C ≤ T <sub>A</sub> ≤ 105 °C | 1017 | 1022 | —    | LSB     | <a href="#">D</a> |
| P <sub>MIN</sub>            | Proof pressure, 90 kPa   | T <sub>A</sub> = 125 °C          | —    | 2    | 14   | LSB     | <a href="#">D</a> |
| P <sub>CODE</sub>           | Proof pressure, 100 kPa  | T <sub>A</sub> = 125 °C          | 1    | 12   | 23   | LSB     | <a href="#">A</a> |
| P <sub>CODE</sub>           | Proof pressure, 260 kPa  | T <sub>A</sub> = 125 °C          | 161  | 172  | 183  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 300 kPa  | T <sub>A</sub> = 125 °C          | 201  | 212  | 223  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 430 kPa  | T <sub>A</sub> = 125 °C          | 331  | 342  | 353  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 600 kPa  | T <sub>A</sub> = 125 °C          | 501  | 512  | 523  | LSB     | <a href="#">C</a> |
| P <sub>CODE</sub>           | Proof pressure, 770 kPa  | T <sub>A</sub> = 125 °C          | 671  | 682  | 693  | LSB     | <a href="#">C</a> |

**Table 15. Pressure measurement characteristics (90 kPa to 1110 kPa) range...continued**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer function:  $P \text{ kPa} = (1.0 \text{ kPa} / \text{LSB} \times P_{\text{CODE}}) + 88.0 \text{ kPa}$

Interpolated limits between 105 °C and 125 °C.

| Symbol             | Parameter                | Conditions              | Min  | Typ  | Max | Unit | Notes             |
|--------------------|--------------------------|-------------------------|------|------|-----|------|-------------------|
| P <sub>CODE</sub>  | Proof pressure, 800 kPa  | T <sub>A</sub> = 125 °C | 701  | 712  | 723 | LSB  | <a href="#">A</a> |
| P <sub>CODE</sub>  | Proof pressure, 940 kPa  | T <sub>A</sub> = 125 °C | 841  | 852  | 863 | LSB  | <a href="#">C</a> |
| P <sub>CODE</sub>  | Proof pressure, 1050 kPa | T <sub>A</sub> = 125 °C | 951  | 962  | 973 | LSB  | <a href="#">A</a> |
| P <sub>MAX</sub>   | Proof pressure, 1110 kPa | T <sub>A</sub> = 125 °C | 1011 | 1022 | —   | LSB  | <a href="#">D</a> |
| P <sub>DRIFT</sub> | Pressure drift           | —                       | –8   | —    | +8  | LSB  | <a href="#">C</a> |

## 6.11 Acceleration measurement characteristics

Unless otherwise noted, stated tolerances are valid only with Initial Sample Delay [ISD3:0] set for > 2.5 ms and MCU placed in STOP4 mode.

### 6.11.1 Acceleration measurement characteristics (–80 g to +90 g) range option

**Table 16. Acceleration measurement characteristic (–80 g to +90 g) range option**

$V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7 A g's =  $(0.020 \text{ g/LSB} \times A_{\text{CODE}}) - 10.039 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

| Symbol                | Parameter                                      | Conditions                      | Min   | Typ   | Max   | Unit    | Notes             |
|-----------------------|------------------------------------------------|---------------------------------|-------|-------|-------|---------|-------------------|
| DA <sub>MAX-MIN</sub> | Sensitivity                                    | —                               | 0.014 | 0.020 | 0.034 | g / LSB | <a href="#">C</a> |
| A <sub>ERROR</sub>    | Error                                          | —                               | —     | 0     | —     | LSB     | <a href="#">C</a> |
| A <sub>UNDER</sub>    | Underflow                                      | FW error status bit 0 = 1       | —     | 1     | —     | LSB     | <a href="#">C</a> |
| A <sub>OVER</sub>     | Overflow                                       | FW error status bit 0 = 1       | —     | 1023  | —     | LSB     | <a href="#">C</a> |
| A <sub>MIN0</sub>     | Acceleration measurement, –80 g, Offset step 0 | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | —     | 2     | —     | LSB     | <a href="#">D</a> |
| A <sub>CODE0</sub>    | Acceleration measurement, –75 g, Offset Step 0 | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | —     | 257   | —     | LSB     | <a href="#">D</a> |
| A <sub>CODE0</sub>    | Acceleration measurement, –70 g, Offset Step 0 | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | —     | 512   | —     | LSB     | <a href="#">D</a> |
| A <sub>CODE0</sub>    | Acceleration measurement, –65 g, Offset Step 0 | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | —     | 767   | —     | LSB     | <a href="#">D</a> |
| A <sub>MAX0</sub>     | Acceleration measurement, –60 g, Offset Step 0 | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | —     | 1022  | —     | LSB     | <a href="#">D</a> |
| A <sub>MIN7</sub>     | Acceleration measurement, –10 g, Offset Step 7 | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | —     | 2     | 180   | LSB     | <a href="#">D</a> |
| A <sub>CODE7</sub>    | Acceleration measurement, –5 g, Offset Step 7  | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | 104   | 257   | 410   | LSB     | <a href="#">D</a> |
| A <sub>CODE7</sub>    | Acceleration measurement, 0 g, Offset Step 7   | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | 384   | 512   | 640   | LSB     | <a href="#">A</a> |
| A <sub>CODE7</sub>    | Acceleration measurement, 5 g, Offset Step 7   | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | 614   | 767   | 920   | LSB     | <a href="#">D</a> |
| A <sub>MAX7</sub>     | Acceleration measurement, 10 g, Offset Step 7  | –20 °C ≤ T <sub>A</sub> ≤ 85 °C | 844   | 1022  | —     | LSB     | <a href="#">D</a> |

**Table 16. Acceleration measurement characteristic (–80 g to +90 g) range option...continued**

$V_{DD5} \text{ Min} \leq V_{DD} \leq V_{DD5} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7  $A \text{ g's} = (0.020 \text{ g/LSB} \times A_{CODE}) - 10.039 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

| Symbol       | Parameter                                      | Conditions                                 | Min | Typ  | Max | Unit | Notes             |
|--------------|------------------------------------------------|--------------------------------------------|-----|------|-----|------|-------------------|
| $A_{MIN7}$   | Acceleration measurement, –10 g, Offset Step 7 | $T_A = -40\text{ °C and }125\text{ °C}$    | —   | 2    | 216 | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, –5 g, Offset Step 7  | $T_A = -40\text{ °C and }125\text{ °C}$    | 73  | 257  | 441 | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, 0 g, Offset Step 7   | $T_A = -40\text{ °C and }125\text{ °C}$    | 359 | 512  | 665 | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, 5 g, Offset Step 7   | $T_A = -40\text{ °C and }125\text{ °C}$    | 583 | 767  | 951 | LSB  | <a href="#">D</a> |
| $A_{MAX7}$   | Acceleration measurement, 10 g, Offset Step 7  | $T_A = -40\text{ °C and }125\text{ °C}$    | 808 | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{MIN15}$  | Acceleration measurement, 70 g, Offset Step 15 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 2    | —   | LSB  | <a href="#">D</a> |
| $A_{CODE15}$ | Acceleration measurement, 75 g, Offset Step 15 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 257  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE15}$ | Acceleration measurement, 80 g, Offset Step 15 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 512  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE15}$ | Acceleration measurement, 85 g, Offset Step 15 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 767  | —   | LSB  | <a href="#">D</a> |
| $A_{MAX15}$  | Acceleration measurement, 90 g, Offset Step 15 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{DRIFT}$  | Inertia drift                                  | —                                          | –5  | —    | +5  | LSB  | <a href="#">C</a> |

### 6.11.2 Acceleration measurement characteristic (–360 g to +400 g) range option

**Table 17. Acceleration measurement characteristic (–360 g to +400 g) range option**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7  $A \text{ g's} = (0.088 \text{ g/LSB} \times A_{CODE}) - 45.176 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

| Symbol           | Parameter                                       | Conditions                                 | Min   | Typ   | Max   | Unit    | Notes             |
|------------------|-------------------------------------------------|--------------------------------------------|-------|-------|-------|---------|-------------------|
| $DdrA_{MAX-MIN}$ | Sensitivity                                     | —                                          | 0.074 | 0.088 | 0.108 | g / LSB | <a href="#">C</a> |
| $A_{ERROR}$      | Error                                           | —                                          | —     | 0     | —     | LSB     | <a href="#">C</a> |
| $A_{UNDER}$      | Underflow                                       | FW error status bit 0 = 1                  | —     | 1     | —     | LSB     | <a href="#">C</a> |
| $A_{OVER}$       | Overflow                                        | FW error status bit 0 = 1                  | —     | 1023  | —     | LSB     | <a href="#">C</a> |
| $A_{MIN0}$       | Acceleration measurement, –360 g, Offset step 0 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —     | 2     | —     | LSB     | <a href="#">D</a> |
| $A_{CODE0}$      | Acceleration measurement, –338 g, Offset step 0 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —     | 257   | —     | LSB     | <a href="#">D</a> |
| $A_{CODE0}$      | Acceleration measurement, –315 g, Offset step 0 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —     | 512   | —     | LSB     | <a href="#">D</a> |
| $A_{CODE0}$      | Acceleration measurement, –293 g, Offset step 0 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —     | 767   | —     | LSB     | <a href="#">D</a> |
| $A_{MAX0}$       | Acceleration measurement, –270 g, Offset step 0 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —     | 1022  | —     | LSB     | <a href="#">D</a> |

**Table 17. Acceleration measurement characteristic (–360 g to +400 g) range option...continued**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7 A g's =  $(0.088 \text{ g/LSB} \times A_{CODE}) - 45.176 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

| Symbol       | Parameter                                        | Conditions                                 | Min | Typ  | Max | Unit | Notes             |
|--------------|--------------------------------------------------|--------------------------------------------|-----|------|-----|------|-------------------|
| $A_{MIN7}$   | Acceleration measurement, –45 g, Offset step 7   | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 2    | 81  | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, –22.5 g, Offset step 7 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | 203 | 257  | 311 | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, 0 g, Offset step 7     | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | 483 | 512  | 541 | LSB  | <a href="#">A</a> |
| $A_{CODE7}$  | Acceleration measurement, 22.5 g, Offset step 7  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | 713 | 767  | 821 | LSB  | <a href="#">D</a> |
| $A_{MAX7}$   | Acceleration measurement, 45 g, Offset step 7    | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | 943 | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{MIN7}$   | Acceleration measurement, –45 g, Offset step 7   | $T_A = -40\text{ °C and } 125\text{ °C}$   | —   | 2    | 97  | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, –22.5 g, Offset step 7 | $T_A = -40\text{ °C and } 125\text{ °C}$   | 192 | 257  | 322 | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, 0 g, Offset step 7     | $T_A = -40\text{ °C and } 125\text{ °C}$   | 478 | 512  | 546 | LSB  | <a href="#">D</a> |
| $A_{CODE7}$  | Acceleration measurement, 22.5 g, Offset step 7  | $T_A = -40\text{ °C and } 125\text{ °C}$   | 702 | 767  | 832 | LSB  | <a href="#">D</a> |
| $A_{MAX7}$   | Acceleration measurement, 45 g, Offset step 7    | $T_A = -40\text{ °C and } 125\text{ °C}$   | 927 | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{MIN15}$  | Acceleration measurement, 315 g, Offset Step 15  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 2    | —   | LSB  | <a href="#">D</a> |
| $A_{CODE15}$ | Acceleration measurement, 338 g, Offset Step 15  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 257  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE15}$ | Acceleration measurement, 360 g, Offset Step 15  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 512  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE15}$ | Acceleration measurement, 383 g, Offset Step 15  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 767  | —   | LSB  | <a href="#">D</a> |
| $A_{MAX15}$  | Acceleration measurement, 405 g, Offset Step 15  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{DRIFT}$  | Acceleration measurement drift                   | —                                          | –4  | —    | +4  | LSB  | <a href="#">C</a> |

### 6.11.3 Acceleration measurement characteristic (–175 g to +550 g) range option

**Table 18. Acceleration measurement characteristic (–175 g to +550 g) range option**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7 A g's =  $(0.343 \text{ g/LSB} \times A_{CODE}) - 175.686 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Due to the inverted polarity calibration where the offset steps are in reverse order, the standard library function `TPMS_READ_DYNAMIC_ACCEL` is not compatible with this range option.

| Symbol               | Parameter   | Conditions                | Min   | Typ   | Max   | Unit    | Notes             |
|----------------------|-------------|---------------------------|-------|-------|-------|---------|-------------------|
| $\Delta A_{MAX-MIN}$ | Sensitivity |                           | 0.302 | 0.343 | 0.398 | g / LSB | <a href="#">C</a> |
| $A_{ERROR}$          | Error       |                           |       | 0     |       | LSB     | <a href="#">C</a> |
| $A_{UNDER}$          | Underflow   | FW error status bit 0 = 1 |       | 1     |       | LSB     | <a href="#">C</a> |
| $A_{OVER}$           | Overflow    | FW error status bit 0 = 1 |       | 1023  |       | LSB     | <a href="#">C</a> |

**Table 18. Acceleration measurement characteristic (–175 g to +550 g) range option...continued**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7 A g's =  $(0.343 \text{ g/LSB} \times A_{CODE}) - 175.686 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Due to the inverted polarity calibration where the offset steps are in reverse order, the standard library function

TPMS\_READ\_DYNAMIC\_ACCEL is not compatible with this range option.

| Symbol              | Parameter                                       | Conditions           | Min | Typ  | Max | Unit | Notes             |
|---------------------|-------------------------------------------------|----------------------|-----|------|-----|------|-------------------|
| A <sub>MIN4</sub>   | Acceleration measurement, 200 g, Offset step 4  | –20 °C ≤ TA ≤ 85 °C  | —   | 2    | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE4</sub>  | Acceleration measurement, 288 g, Offset step 4  | –20 °C ≤ TA ≤ 85 °C  | —   | 257  | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE4</sub>  | Acceleration measurement, 375 g, Offset step 4  | –20 °C ≤ TA ≤ 85 °C  | —   | 512  | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE4</sub>  | Acceleration measurement, 463 g, Offset step 4  | –20 °C ≤ TA ≤ 85 °C  | —   | 767  | —   | LSB  | <a href="#">D</a> |
| A <sub>MAX4</sub>   | Acceleration measurement, 550 g, Offset step 4  | –20 °C ≤ TA ≤ 85 °C  | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| A <sub>MIN5</sub>   | Acceleration measurement, 75 g, Offset step 5   | –20 °C ≤ TA ≤ 85 °C  | —   | 2    | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE5</sub>  | Acceleration measurement, 163 g, Offset step 5  | –20 °C ≤ TA ≤ 85 °C  | —   | 257  | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE5</sub>  | Acceleration measurement, 250 g, Offset step 5  | –20 °C ≤ TA ≤ 85 °C  | —   | 512  | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE5</sub>  | Acceleration measurement, 338 g, Offset step 5  | –20 °C ≤ TA ≤ 85 °C  | —   | 767  | —   | LSB  | <a href="#">D</a> |
| A <sub>MAX5</sub>   | Acceleration measurement, 425 g, Offset step 5  | –20 °C ≤ TA ≤ 85 °C  | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| A <sub>MIN6</sub>   | Acceleration measurement, –50 g, Offset step 6  | –20 °C ≤ TA ≤ 85 °C  | —   | 2    | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE6</sub>  | Acceleration measurement, 38 g, Offset step 6   | –20 °C ≤ TA ≤ 85 °C  | —   | 257  | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE6</sub>  | Acceleration measurement, 125 g, Offset step 6  | –20 °C ≤ TA ≤ 85 °C  | —   | 512  | —   | LSB  | <a href="#">D</a> |
| A <sub>CODE6</sub>  | Acceleration measurement, 213 g, Offset step 6  | –20 °C ≤ TA ≤ 85 °C  | —   | 767  | —   | LSB  | <a href="#">D</a> |
| A <sub>MAX6</sub>   | Acceleration measurement, 300 g, Offset step 6  | –20 °C ≤ TA ≤ 85 °C  | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| A <sub>MIN 7</sub>  | Acceleration measurement, –175 g, Offset step 7 | –20 °C ≤ TA ≤ 85 °C  | —   | 2    | 60  | LSB  | <a href="#">D</a> |
| A <sub>CODE 7</sub> | Acceleration measurement, –88 g, Offset step 7  | –20 °C ≤ TA ≤ 85 °C  | 224 | 257  | 290 | LSB  | <a href="#">D</a> |
| A <sub>CODE 7</sub> | Acceleration measurement, 0 g, Offset step 7    | –20 °C ≤ TA ≤ 85 °C  | 504 | 512  | 520 | LSB  | <a href="#">A</a> |
| A <sub>CODE 7</sub> | Acceleration measurement, 88 g, Offset step 7   | –20 °C ≤ TA ≤ 85 °C  | 734 | 767  | 800 | LSB  | <a href="#">D</a> |
| A <sub>MAX 7</sub>  | Acceleration measurement, 175 g, Offset step 7  | –20 °C ≤ TA ≤ 85 °C  | 964 | 1022 | —   | LSB  | <a href="#">D</a> |
| A <sub>MIN 7</sub>  | Acceleration measurement, –175 g, Offset step 7 | TA = –40 °C & 125 °C | —   | 2    | 72  | LSB  | <a href="#">D</a> |
| A <sub>CODE 7</sub> | Acceleration measurement, –88 g, Offset step 7  | TA = –40 °C & 125 °C | 218 | 257  | 296 | LSB  | <a href="#">D</a> |

**Table 18. Acceleration measurement characteristic (–175 g to +550 g) range option...continued**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7  $A \text{ g's} = (0.343 \text{ g/LSB} \times A_{CODE}) - 175.686 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Due to the inverted polarity calibration where the offset steps are in reverse order, the standard library function

TPMS\_READ\_DYNAMIC\_ACCEL is not compatible with this range option.

| Symbol        | Parameter                                           | Conditions                                 | Min | Typ  | Max | Unit | Notes             |
|---------------|-----------------------------------------------------|--------------------------------------------|-----|------|-----|------|-------------------|
| $A_{CODE} 7$  | Acceleration measurement, 0 g,<br>Offset step 7     | $T_A = -40\text{ °C} \ \& \ 125\text{ °C}$ | 503 | 512  | 525 | LSB  | <a href="#">D</a> |
| $A_{CODE} 7$  | Acceleration measurement, 88 g,<br>Offset step 7    | $T_A = -40\text{ °C} \ \& \ 125\text{ °C}$ | 728 | 767  | 806 | LSB  | <a href="#">D</a> |
| $A_{MAX} 7$   | Acceleration measurement, 175 g,<br>Offset step 7   | $T_A = -40\text{ °C} \ \& \ 125\text{ °C}$ | 952 | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{MIN} 8$   | Acceleration measurement, –300 g,<br>Offset step 8  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 2    | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 8$  | Acceleration measurement, –213 g,<br>Offset step 8  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 257  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 8$  | Acceleration measurement, –125 g,<br>Offset step 8  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 512  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 8$  | Acceleration measurement, –38 g,<br>Offset step 8   | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 767  | —   | LSB  | <a href="#">D</a> |
| $A_{MAX} 8$   | Acceleration measurement, 50 g,<br>Offset step 8    | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{MIN} 9$   | Acceleration measurement, –425 g,<br>Offset step 9  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 2    | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 9$  | Acceleration measurement, –338 g,<br>Offset step 9  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 257  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 9$  | Acceleration measurement, –250 g,<br>Offset step 9  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 512  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 9$  | Acceleration measurement, –163 g,<br>Offset step 9  | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 767  | —   | LSB  | <a href="#">D</a> |
| $A_{MAX} 9$   | Acceleration measurement, –75 g,<br>Offset step 9   | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{MIN} 10$  | Acceleration measurement, –550 g,<br>Offset step 10 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 2    | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 10$ | Acceleration measurement, –463 g,<br>Offset step 10 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 257  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 10$ | Acceleration measurement, –375 g,<br>Offset step 10 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 512  | —   | LSB  | <a href="#">D</a> |
| $A_{CODE} 10$ | Acceleration measurement, –288 g,<br>Offset step 10 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 767  | —   | LSB  | <a href="#">D</a> |
| $A_{MAX} 10$  | Acceleration measurement, –200 g,<br>Offset step 10 | $-20\text{ °C} \leq T_A \leq 85\text{ °C}$ | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{DRIFT}$   | Inertia drift                                       |                                            | –4  |      | +4  | LSB  | <a href="#">C</a> |

#### 6.11.4 Acceleration measurement characteristic (–400 g to +400 g) range option

**Table 19. Acceleration measurement characteristic (–400 g to +400 g) range option**

$V_{DDM\ Min} \leq V_{DD} \leq V_{DDM\ Max}$ ,  $T_{AS\ Min} \leq T_A \leq T_{AS\ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7  $A\ g's = (0.294\ g/LSB \times A_{CODE}) - 150.59\ g$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

| Symbol               | Parameter                                       | Conditions                | Min   | Typ   | Max   | Unit    | Notes             |
|----------------------|-------------------------------------------------|---------------------------|-------|-------|-------|---------|-------------------|
| $\Delta A_{MAX-MIN}$ | Sensitivity                                     |                           | 0.260 | 0.294 | 0.342 | g / LSB | <a href="#">C</a> |
| $A_{ERROR}$          | Error                                           |                           |       | 0     |       | LSB     | <a href="#">C</a> |
| $A_{UNDER}$          | Underflow                                       | FW error status bit 0 = 1 |       | 1     |       | LSB     | <a href="#">C</a> |
| $A_{OVER}$           | Overflow                                        | FW error status bit 0 = 1 |       | 1023  |       | LSB     | <a href="#">C</a> |
| $A_{MIN\ 6}$         | Acceleration measurement, –400 g, Offset step 6 | –20 °C ≤ TA ≤ 85 °C       | —     | 2     | —     | LSB     | <a href="#">D</a> |
| $A_{CODE\ 6}$        | Acceleration measurement, –325 g, Offset step 6 | –20 °C ≤ TA ≤ 85 °C       | —     | 257   | —     | LSB     | <a href="#">D</a> |
| $A_{CODE\ 6}$        | Acceleration measurement, –250 g, Offset step 6 | –20 °C ≤ TA ≤ 85 °C       | —     | 512   | —     | LSB     | <a href="#">D</a> |
| $A_{CODE\ 6}$        | Acceleration measurement, –175 g, Offset step 6 | –20 °C ≤ TA ≤ 85 °C       | —     | 767   | —     | LSB     | <a href="#">D</a> |
| $A_{MAX\ 6}$         | Acceleration measurement, –100 g, Offset step 6 | –20 °C ≤ TA ≤ 85 °C       | —     | 1022  | —     | LSB     | <a href="#">D</a> |
| $A_{MIN\ 7}$         | Acceleration measurement, –150 g, Offset step 7 | –20 °C ≤ TA ≤ 85 °C       | —     | 2     | 61    | LSB     | <a href="#">D</a> |
| $A_{CODE\ 7}$        | Acceleration measurement, –75 g, Offset step 7  | –20 °C ≤ TA ≤ 85 °C       | 223   | 257   | 291   | LSB     | <a href="#">D</a> |
| $A_{CODE\ 7}$        | Acceleration measurement, 0 g, Offset step 7    | –20 °C ≤ TA ≤ 85 °C       | 503   | 512   | 521   | LSB     | <a href="#">A</a> |
| $A_{CODE\ 7}$        | Acceleration measurement, 75 g, Offset step 7   | –20 °C ≤ TA ≤ 85 °C       | 733   | 767   | 801   | LSB     | <a href="#">D</a> |
| $A_{MAX\ 7}$         | Acceleration measurement, 150 g, Offset step 7  | –20 °C ≤ TA ≤ 85 °C       | 963   | 1022  | —     | LSB     | <a href="#">D</a> |
| $A_{MIN\ 7}$         | Acceleration measurement, –150 g, Offset step 7 | TA = –40 °C & 125 °C      | —     | 2     | 73    | LSB     | <a href="#">D</a> |
| $A_{CODE\ 7}$        | Acceleration measurement, –75 g, Offset step 7  | TA = –40 °C & 125 °C      | 216   | 257   | 298   | LSB     | <a href="#">D</a> |
| $A_{CODE\ 7}$        | Acceleration measurement, 0 g, Offset step 7    | TA = –40 °C & 125 °C      | 501   | 512   | 523   | LSB     | <a href="#">D</a> |
| $A_{CODE\ 7}$        | Acceleration measurement, 75 g, Offset step 7   | TA = –40 °C & 125 °C      | 726   | 767   | 808   | LSB     | <a href="#">D</a> |
| $A_{MAX\ 7}$         | Acceleration measurement, 150 g, Offset step 7  | TA = –40 °C & 125 °C      | 951   | 1022  | —     | LSB     | <a href="#">D</a> |
| $A_{MIN\ 8}$         | Acceleration measurement, 100 g, Offset step 8  | –20 °C ≤ TA ≤ 85 °C       | —     | 2     | —     | LSB     | <a href="#">D</a> |
| $A_{CODE\ 8}$        | Acceleration measurement, 175 g, Offset step 8  | –20 °C ≤ TA ≤ 85 °C       | —     | 257   | —     | LSB     | <a href="#">D</a> |
| $A_{CODE\ 8}$        | Acceleration measurement, 250 g, Offset step 8  | –20 °C ≤ TA ≤ 85 °C       | —     | 512   | —     | LSB     | <a href="#">D</a> |
| $A_{CODE\ 8}$        | Acceleration measurement, 325 g, Offset step 8  | –20 °C ≤ TA ≤ 85 °C       | —     | 767   | —     | LSB     | <a href="#">D</a> |

**Table 19. Acceleration measurement characteristic (–400 g to +400 g) range option...continued**

$V_{DDM} \text{ Min} \leq V_{DD} \leq V_{DDM} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

Transfer Function: Offset Step 7 A g's =  $(0.294 \text{ g/LSB} \times A_{CODE}) - 150.59 \text{ g}$

Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

| Symbol              | Parameter                                      | Conditions                    | Min | Typ  | Max | Unit | Notes             |
|---------------------|------------------------------------------------|-------------------------------|-----|------|-----|------|-------------------|
| $A_{\text{MAX } 8}$ | Acceleration measurement, 400 g, Offset step 8 | –20 °C $\leq$ TA $\leq$ 85 °C | —   | 1022 | —   | LSB  | <a href="#">D</a> |
| $A_{\text{DRIFT}}$  | Inertia drift                                  |                               | –5  |      | +5  | LSB  | <a href="#">C</a> |

## 6.12 Low frequency receiver characteristics

**Table 20. LFR characteristics**

$V_{DDF} \text{ Min} \leq V_{DD} \leq V_{DDF} \text{ Max}$ ,  $T_{AF} \text{ Min} \leq T_A \leq T_{AF} \text{ Max}$ , unless otherwise specified.

| Symbol               | Parameter                                           | Conditions               | Min       | Typ     | Max        | Unit  | Notes             |
|----------------------|-----------------------------------------------------|--------------------------|-----------|---------|------------|-------|-------------------|
| $R_{\text{LDFD}}$    | LFA / LFB load resistance                           | —                        | 0.8       | —       | 4          | MΩ    | <a href="#">D</a> |
| $DR_{\text{LFIN}}$   | Dynamic range, $f_c$ at $BW_{\text{ACC}}$           | Data mode, always detect | 56        | —       | —          | dB    | <a href="#">D</a> |
| $V_{\text{IN-AD-H}}$ | Sensitivity, high - carrier and data modes          | Always detect            | —         | —       | 3.0        | mVPP  | <a href="#">B</a> |
| $V_{\text{IN-ND-H}}$ | Sensitivity, high - carrier and data modes          | Never detect             | 0.25      | —       | —          | mVPP  | <a href="#">B</a> |
| $V_{\text{IN-AD-L}}$ | Sensitivity, low - carrier and data modes           | Always detect            | —         | —       | 12.0       | mVPP  | <a href="#">B</a> |
| $V_{\text{IN-ND-L}}$ | Sensitivity, low - carrier and data modes           | Never detect             | 4.0       | —       | —          | mVPP  | <a href="#">B</a> |
| MD                   | Modulation depth                                    | —                        | 70        | —       | 100        | %     | <a href="#">C</a> |
| BRLF                 | Baud rate                                           | —                        | 3788      | 3906    | 4032       | Bit/s | <a href="#">C</a> |
| DCM                  | Manchester duty cycle tolerance                     | —                        | —         | 40 / 60 | 45 / 55    | %     | <a href="#">C</a> |
| DCN                  | NRZ duty cycle tolerance                            | —                        | —         | 50 / 50 | 45 / 55    | %     | <a href="#">C</a> |
| MER                  | Message error rate                                  | —                        | —         | 5       | —          | %     | <a href="#">C</a> |
| $BW_{\text{ACC}}$    | Bandwidth                                           | Always detect            | $\geq 88$ | —       | $\leq 175$ | kHz   | <a href="#">C</a> |
| $BW_{\text{REJ}}$    | Bandwidth                                           | Never detect             | $< 88$    | —       | $> 175$    | kHz   | <a href="#">C</a> |
| $t_{\text{LF}}$      | Signal rise / decay time constant, carrier envelope | —                        | 15.3      | —       | —          | μs    | <a href="#">D</a> |

## 6.13 Radio frequency transmitter characteristics

**Table 21. Radio frequency transmitter characteristics**

$V_{DDs} \text{ Min} \leq V_{DD} \leq V_{DDs} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

All conditions characterized with NDK NX2016SA 26.000 MHz crystal.

| Symbol  | Parameter                                                      | Conditions                                    | Min  | Typ | Max | Unit | Notes             |
|---------|----------------------------------------------------------------|-----------------------------------------------|------|-----|-----|------|-------------------|
| PRF3    | Nominal output power with 50 Ω matching network <sup>[1]</sup> | 315 MHz, 25 °C, 3.0 V<br>PWR[4:0] = 0 1 1 0 0 | —    | 5   | —   | dBm  | <a href="#">C</a> |
| PRF4    | Nominal output power with 50 Ω matching network <sup>[1]</sup> | 434 MHz, 25 °C, 3.0 V<br>PWR[4:0] = 0 1 1 1 0 | —    | 5   | —   | dBm  | <a href="#">C</a> |
| PRF     | Output power, range                                            | —                                             | –1.5 | —   | 8   | dBm  | <a href="#">C</a> |
| PRFSTEP | Output power, step size                                        | —                                             | —    | 0.5 | —   | dBm  | <a href="#">C</a> |

**Table 21. Radio frequency transmitter characteristics...continued***V<sub>DDS</sub> Min ≤ V<sub>DD</sub> ≤ V<sub>DDS</sub> Max, T<sub>AS</sub> Min ≤ T<sub>A</sub> ≤ T<sub>AS</sub> Max, unless otherwise specified.**All conditions characterized with NDK NX2016SA 26.000 MHz crystal.*

| Symbol              | Parameter                                                                                                                             | Conditions                                                                                                                                | Min | Typ  | Max  | Unit      | Notes             |
|---------------------|---------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------|-----|------|------|-----------|-------------------|
| PRFMINp             | Output power, minimum PRF vs. T <sub>A</sub> and V <sub>DD</sub> under control of FW TPMS_RF_DYNAMIC_POWER                            | -40 °C ≤ T <sub>A</sub> ≤ 0 °C and 1.8 V ≤ V <sub>DD</sub> ≤ 2.5 V, or 0 °C ≤ T <sub>A</sub> ≤ 125 °C and 2.5 V ≤ V <sub>DD</sub> ≤ 3.6 V | 3   | —    | —    | dBm       | <a href="#">C</a> |
| PRFMINn             | Output power, minimum PRF vs. T <sub>A</sub> and V <sub>DD</sub> under control of FW TPMS_RF_DYNAMIC_POWER                            | 25 °C ≤ T <sub>A</sub> ≤ 60 °C and 2.5 V ≤ V <sub>DD</sub> ≤ 3.6 V                                                                        | 5   | —    | —    | dBm       | <a href="#">C</a> |
| PRFMIN00            | Output power, Step = 00                                                                                                               | —                                                                                                                                         | —   | -10  | —    | dBm       | <a href="#">C</a> |
| FSK                 | Frequency shift key step                                                                                                              | —                                                                                                                                         | —   | 3.17 | —    | kHz       | <a href="#">D</a> |
| MOOK                | On off key modulation depth                                                                                                           | —                                                                                                                                         | 60  | 80   | —    | dBc       | <a href="#">C</a> |
| BRRF                | Baud rate range                                                                                                                       | —                                                                                                                                         | 1.2 | —    | 38.4 | kbits/sec | <a href="#">C</a> |
| DR                  | Manchester encoding bit/s accuracy, based on MFO                                                                                      | —                                                                                                                                         | -5  | —    | +5   | %         | <a href="#">D</a> |
| DC                  | Modulation duty cycle, FSK, and OOK                                                                                                   | —                                                                                                                                         | 45  | 50   | 55   | %         | <a href="#">C</a> |
| FxTAL               | External crystal frequency, all conditions                                                                                            | —                                                                                                                                         | —   | 26   | —    | MHz       | <a href="#">D</a> |
| t <sub>S-RCTS</sub> | Fixed portion, RF start-up process                                                                                                    | Typ = 25 °C, 3.0 V, Max = TAS Min to Max & V <sub>DDS</sub> Min to Max                                                                    | —   | 500  | 620  | μs        | <a href="#">C</a> |
| Bits                | Variable portion, RF start-up process                                                                                                 | —                                                                                                                                         | —   | 3    | —    | bit times | <a href="#">C</a> |
| tRF2                | Total RF start time, write of SEND bit to start of RF output, at 2000 bit/s, where tRF = tS-RCTS + (Bits * bit/s)^-1                  | Typ = 25 °C, 3.0 V, Max = TAS Min to Max & V <sub>DDS</sub> Min to Max                                                                    | —   | 2    | 2.2  | ms        | <a href="#">C</a> |
| tRF9                | Total RF start time, write of SEND bit to start of RF output, at 9600 bit/s, where tRF = tS-RCTS + (Bits * bit/s)^-1                  | Typ = 25 °C, 3.0 V, Max = TAS Min to Max & V <sub>DDS</sub> Min to Max                                                                    | —   | 800  | 920  | μs        | <a href="#">C</a> |
| tRF20               | Total RF start time, write of SEND bit to start of RF output, at 20000 bit/s, where tRF = tS-RCTS + (Bits * bit/s)^-1                 | Typ = 25 °C, 3.0 V, Max = TAS Min to Max & V <sub>DDS</sub> Min to Max                                                                    | —   | 640  | 760  | μs        | <a href="#">C</a> |
| H2                  | Harmonic 2, 315 MHz or 434 MHz, with 50 Ω matching network <sup>[1]</sup> , power step adjusted to reach target power in each domain. | —                                                                                                                                         | —   | —    | -22  | dBc       | <a href="#">C</a> |
| H3                  | Harmonic 3, 315 MHz or 434 MHz, with 50 Ω matching network <sup>[1]</sup> , power step adjusted to reach target power in each domain. | —                                                                                                                                         | —   | —    | -31  | dBc       | <a href="#">C</a> |
| H4                  | Harmonic 4, 315 MHz or 434 MHz, with 50 Ω matching network <sup>[1]</sup> , power step adjusted to reach target power in each domain. | —                                                                                                                                         | —   | —    | -40  | dBc       | <a href="#">C</a> |
| N3PH10k             | 315 MHz phase noise, ±10 kHz, Boost = 0                                                                                               | Typ = 25 °C, 3.0 V, Max = TAS Min to Max & V <sub>DDS</sub> Min to Max                                                                    | —   | -87  | -78  | dBc / Hz  | <a href="#">C</a> |
| N3PH100k            | 315 MHz phase noise, ±100 kHz, Boost = 0                                                                                              | Typ = 25 °C, 3.0 V, Max = TAS Min to Max & V <sub>DDS</sub> Min to Max                                                                    | —   | -95  | -87  | dBc / Hz  | <a href="#">C</a> |

**Table 21. Radio frequency transmitter characteristics...continued**

$V_{DDS} \text{ Min} \leq V_{DD} \leq V_{DDS} \text{ Max}$ ,  $T_{AS} \text{ Min} \leq T_A \leq T_{AS} \text{ Max}$ , unless otherwise specified.

All conditions characterized with NDK NX2016SA 26.000 MHz crystal.

| Symbol              | Parameter                                                                                                                                           | Conditions                                                    | Min | Typ  | Max  | Unit      | Notes             |
|---------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------|-----|------|------|-----------|-------------------|
| N3PH1M              | 315 MHz phase noise, $\pm 1$ MHz, Boost = 0                                                                                                         | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −82  | −77  | dBc / Hz  | <a href="#">C</a> |
| N31PH10k            | 315 MHz phase noise, $\pm 10$ kHz, Boost = 1                                                                                                        | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −75  | −66  | dBc / Hz  | <a href="#">C</a> |
| N31PH100k           | 315 MHz phase noise, $\pm 100$ kHz, Boost = 1                                                                                                       | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −83  | −75  | dBc / Hz  | <a href="#">C</a> |
| N31PH1M             | 315 MHz phase noise, $\pm 1$ MHz, Boost = 1                                                                                                         | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −96  | −93  | dBc / Hz  | <a href="#">C</a> |
| N4PH10k             | 434 MHz phase noise, $\pm 10$ kHz, Boost = 0                                                                                                        | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −85  | −75  | dBc / Hz  | <a href="#">C</a> |
| N4PH100k            | 434 MHz phase noise, $\pm 100$ kHz, Boost = 0                                                                                                       | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −92  | −83  | dBc / Hz  | <a href="#">C</a> |
| N4PH1M              | 434 MHz phase noise, $\pm 1$ MHz, Boost = 0                                                                                                         | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −83  | −78  | dBc / Hz  | <a href="#">C</a> |
| NPH10M              | Phase noise, $\pm 10$ MHz                                                                                                                           | Typ = 25 °C, 3.0 V, Max = TAS<br>Min to Max & VDDS Min to Max | —   | −105 | −101 | dBc / Hz  | <a href="#">C</a> |
| NSP315              | Spurious noise, <1 GHz, 10 kHz BW<br>315 MHz FCC 15.231a–e                                                                                          | —                                                             | —   | —    | −30  | dBc       | <a href="#">C</a> |
| NSPUG               | Spurious noise, < 1 GHz, 10 kHz BW<br>434 MHz ETSI EN300220                                                                                         | —                                                             | —   | —    | −40  | dBc       | <a href="#">C</a> |
| NSPOG               | Spurious noise, >1 GHz, 10 kHz BW<br>434 MHz ETSI EN300220                                                                                          | —                                                             | —   | —    | −40  | dBc       | <a href="#">C</a> |
| OBWKF               | Occupied bandwidth, < $\pm 35$ kHz FSK<br>up to 19.2 kbit/s Korea, MIC 2007-63                                                                      | —                                                             | —   | —    | 200  | kHz       | <a href="#">C</a> |
| OBWKO               | Occupied bandwidth, OOK up to 9.6<br>kbit/s, Korea, MIC 2007-64                                                                                     | —                                                             | —   | —    | 200  | kHz       | <a href="#">C</a> |
| OBWJF               | Occupied bandwidth, < $\pm 45$ kHz FSK<br>up to 38.4 kbit/s, Japan, ARIB STD-T93                                                                    | —                                                             | —   | —    | 400  | kHz       | <a href="#">C</a> |
| OBWJO               | Occupied bandwidth, OOK up to 19.2<br>kbit/s, Japan, ARIB STD-T94                                                                                   | —                                                             | —   | —    | 600  | kHz       | <a href="#">C</a> |
| ML                  | Oscillation margin                                                                                                                                  | —                                                             | 850 | —    | —    | $\Omega$  | <a href="#">D</a> |
| $f_{XCO}$           | Internal oscillator accuracy                                                                                                                        | —                                                             | −10 | —    | +10  | ppm       | <a href="#">D</a> |
| V <sub>AREGOK</sub> | RF V <sub>reg</sub> capacitor Pre-charge voltage<br>- Note: 0.47 $\mu$ F V <sub>reg</sub> capacitor<br>connected.                                   | V <sub>DDS</sub> $\geq$ 2.1 V                                 | —   | 1.5  | —    | V         | <a href="#">C</a> |
| t <sub>AREGOK</sub> | RF V <sub>reg</sub> capacitor Pre-charge Process<br>- Note: 0.47 $\mu$ F V <sub>reg</sub> capacitor<br>connected, additional to t <sub>S-RCTS</sub> | V <sub>DDS</sub> $\geq$ 2.1 V                                 | —   | 630  | 1000 | $\mu$ Sec | <a href="#">D</a> |

[1] 50  $\Omega$  is the input impedance of the measurement equipment

The firmware routine TPMS\_PRECHARGE\_EN performs the pre-charge of RF V<sub>reg</sub> capacitor. When the pre-charge is successful, the execution time of the routine corresponds to t<sub>AREGOK</sub> duration. When the pre-charge fails, the routine exits after a timeout longer than t<sub>AREGOK</sub> max duration.

6.14 Power consumption RF transmissions

Using the TPMS\_RF\_DYNAMIC\_POWER firmware routine<sup>2</sup> allows adjusting the power step in order to compensate for variations of output power versus temperature and voltage. This routine is associated to a part-to-part trimming that initially adjusts the power step to compensate for process variations.

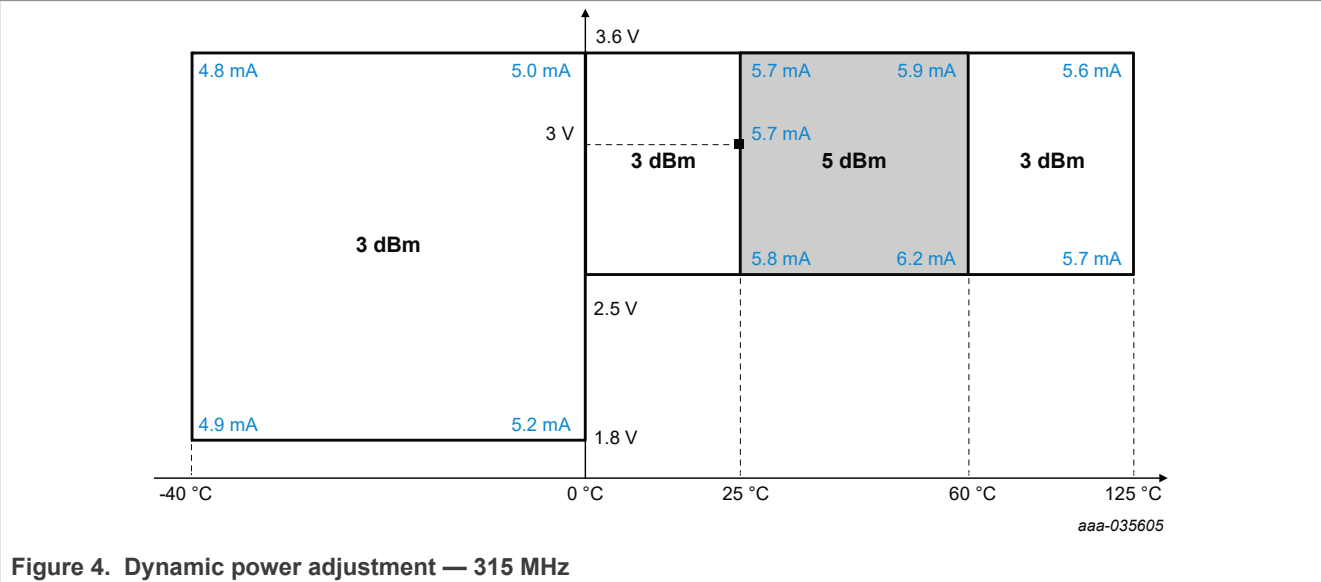


Figure 4. Dynamic power adjustment — 315 MHz

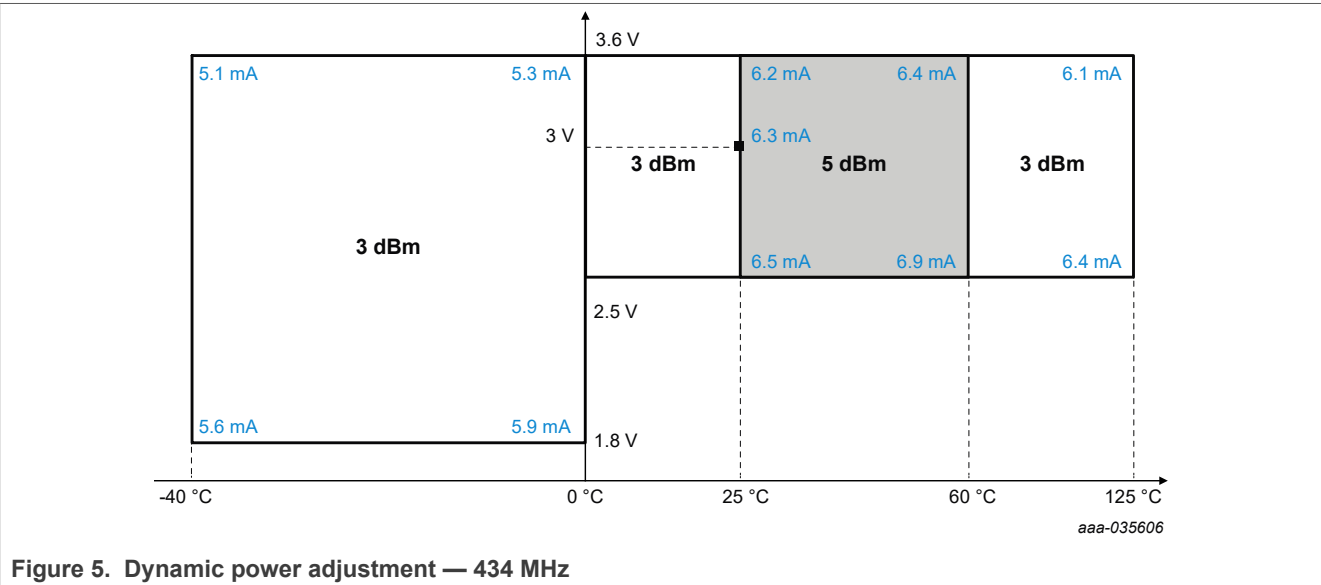
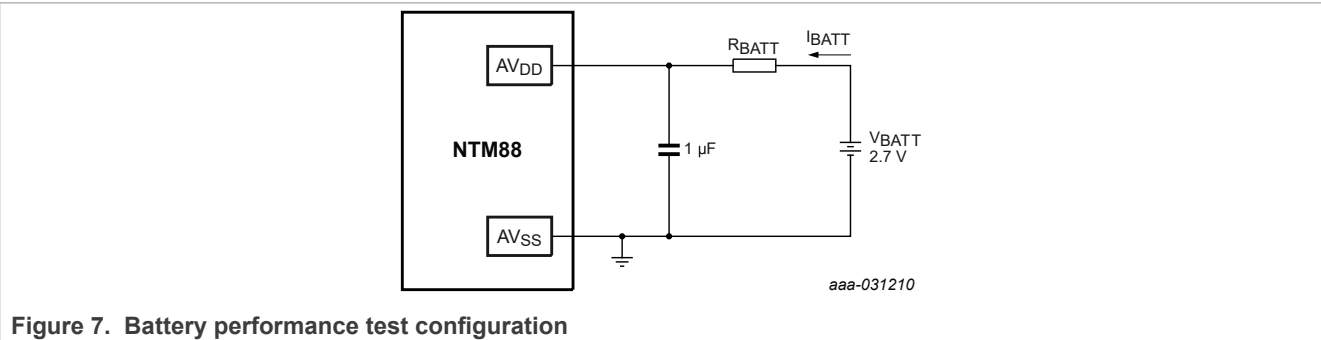
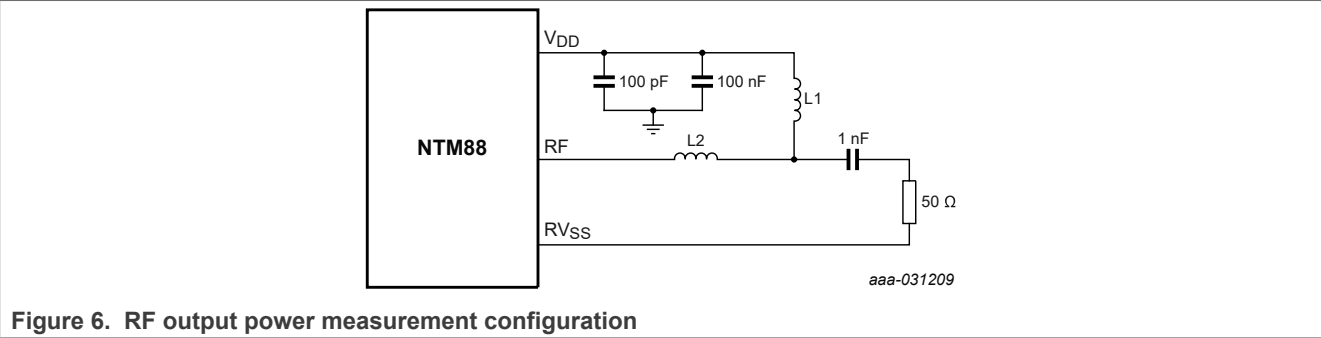


Figure 5. Dynamic power adjustment — 434 MHz

<sup>2</sup> Refer to user manual, UM11227.<sup>[1]</sup>



7 Mechanical specifications

7.1 Maximum ratings (mechanical)

Maximum ratings are the extreme limits the device can be exposed without permanent damage. The device contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than the values shown in [Table 22](#). Keep  $V_{IN}$  and  $V_{OUT}$  within the range  $V_{SS} \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{DD}$ .

Table 22. Maximum ratings

| Symbol        | Parameter                                                 | Conditions                                    | Min  | Typ  | Max  | Unit         | Notes             |
|---------------|-----------------------------------------------------------|-----------------------------------------------|------|------|------|--------------|-------------------|
| $P_{burst1k}$ | Pressure transducer, minimum burst pressure               | $\leq 1200 \text{ kPa}$ rating                | 2000 | —    | —    | kPa          | <a href="#">D</a> |
| $f_{P0}$      | Pressure transducer, minimum natural resonance frequency  | —                                             | —    | 5    | —    | MHz          | <a href="#">D</a> |
| $Q_P$         | Pressure transducer damping ratio                         | —                                             | —    | 1    | —    | —            | <a href="#">D</a> |
| $PA_N$        | Pressure transducer, sensitivity to vertical acceleration | $-500 \text{ g} \leq A \leq +500 \text{ g}$   | —    | 0    | —    | Pa / g       | <a href="#">C</a> |
| $PA_{neg}$    | Pressure transducer, sensitivity to vertical acceleration | $A < -500 \text{ g}$                          | 2    | 4.5  | 6.5  | Pa / g       | <a href="#">C</a> |
| $PA_{pos}$    | Pressure transducer, sensitivity to vertical acceleration | $A > +500 \text{ g}$                          | -6.5 | -4.5 | -2   | Pa / g       | <a href="#">C</a> |
| $f_{A0}$      | Accelerometer, minimum natural resonance frequency        | —                                             | 7    | —    | 16   | kHz          | <a href="#">D</a> |
| $Q_A$         | Accelerometer, damping ratio                              | —                                             | 1    | —    | 4    | —            | <a href="#">D</a> |
| $AP1k$        | Accelerometer, sensitivity to pressure                    | $90 \text{ kPa} \leq P \leq 1200 \text{ kPa}$ | -1.5 | —    | +1.5 | g / 1000 kPa | <a href="#">C</a> |

Table 22. Maximum ratings...continued

| Symbol              | Parameter                                                | Conditions     | Min  | Typ | Max  | Unit | Notes             |
|---------------------|----------------------------------------------------------|----------------|------|-----|------|------|-------------------|
| A <sub>stop2h</sub> | Accelerometer, minimum acceleration to reach travel stop | ≤ 100 g rating | −200 | —   | +200 | g    | <a href="#">D</a> |
| A <sub>stop7h</sub> | Accelerometer, minimum acceleration to reach travel stop | > 100 g rating | −700 | —   | +700 | g    | <a href="#">D</a> |
| m                   | Package Mass                                             | —              | —    | 0.2 | —    | gram | <a href="#">D</a> |
| τ                   | Thermal time constant                                    | —              | —    | 101 | —    | sec  | <a href="#">D</a> |

7.2 Media compatibility

Media compatibility is based on media and test method described in NXP Specification NXPOMS-1719007347-17056.<sup>[2]</sup> Consult your sales representative for more details and specific requirements.

Note:

The devices contain a gel that protects the pressure transducer and its inter-die connection wires from corrosion, which might otherwise result in catastrophic failure modes. NXP has observed that direct exposure to materials with the same or nearly-the-same solubility can potentially result in a corruption of the protective gel. A corruption can be less than catastrophic in nature, however may result in an offset of the pressure measurement from its factory calibrated value. An offset can potentially be larger than the allowed tolerances published in this data sheet.

Further, NXP does not recommend direct exposure to strong acid or strong base compounds as they can potentially result in a similar corruption as described above, or may result in a dissolution of the protective gel and/or the metal lid adhesive and/or the plastic device body. Such a dissolution can be catastrophic in nature, damaging the transducer surfaces and/or internal wire bonds and/or the control die surfaces. A potential dissolution may result in a similar offset, or cause the device to indicate overflow/underflow status, or may cause the device to cease operating in the worst case.

For a list of compounds known to generate out-of-tolerance offsets and/or catastrophic device failure, please contact an NXP sales representative.

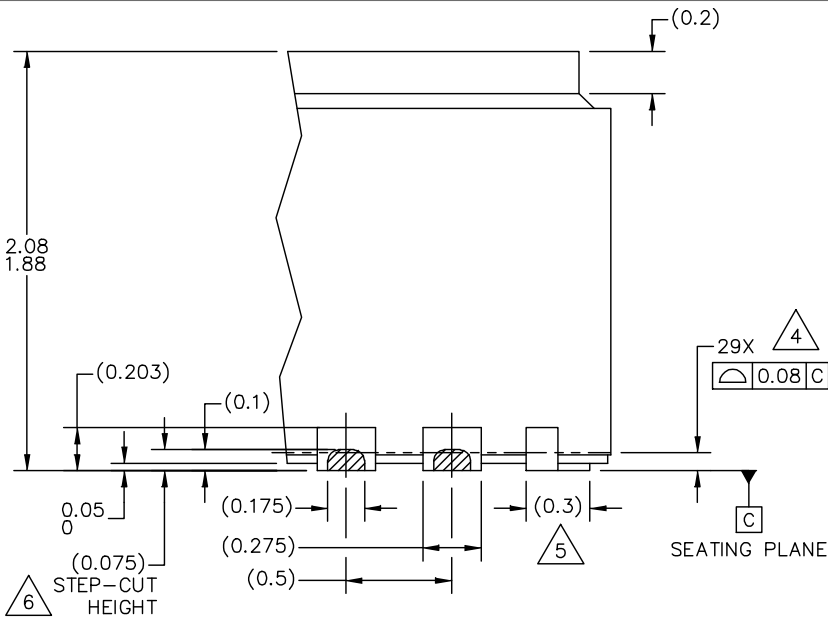
8 Mounting recommendations

The package should be mounted with the pressure port pointing away from the axis of tire rotation. By mounting the pressure port away from the axis of tire rotation, centrifugal force propels any contaminants out of the pressure port. In cases where the application must orient the pressure port pointing inward, care must be taken to assure contaminants do not reach inside the pressure port.

A plugged port exhibits no change in pressure and can be cross checked in the user software. Use the method described in user manual UM11227.<sup>[1]</sup>

Refer to application note AN1902<sup>[3]</sup> for proper printed circuit board attributes and recommendations.





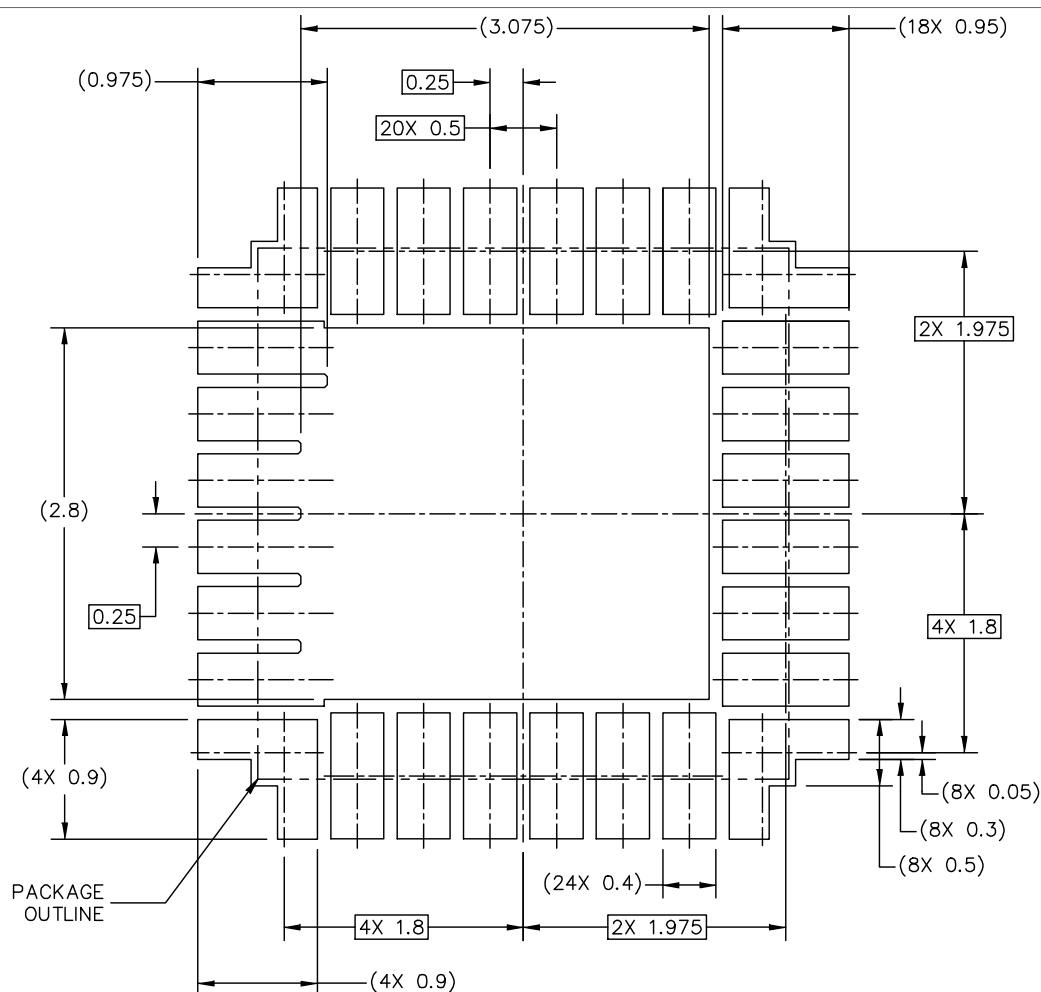
DETAIL E  
VIEW ROTATED 90° CW

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|                                                  |                        |                                |                |  |
|--------------------------------------------------|------------------------|--------------------------------|----------------|--|
| MECHANICAL OUTLINE<br>PRINT VERSION NOT TO SCALE | STANDARD:<br>NON JEDEC | DRAWING NUMBER:<br>98ASA01422D | REVISION:<br>A |  |
|--------------------------------------------------|------------------------|--------------------------------|----------------|--|

Figure 9. Package outline detail HQFN24 (SOT1931-1(D))



## PCB DESIGN GUIDELINES – SOLDER MASK OPENING PATTERN

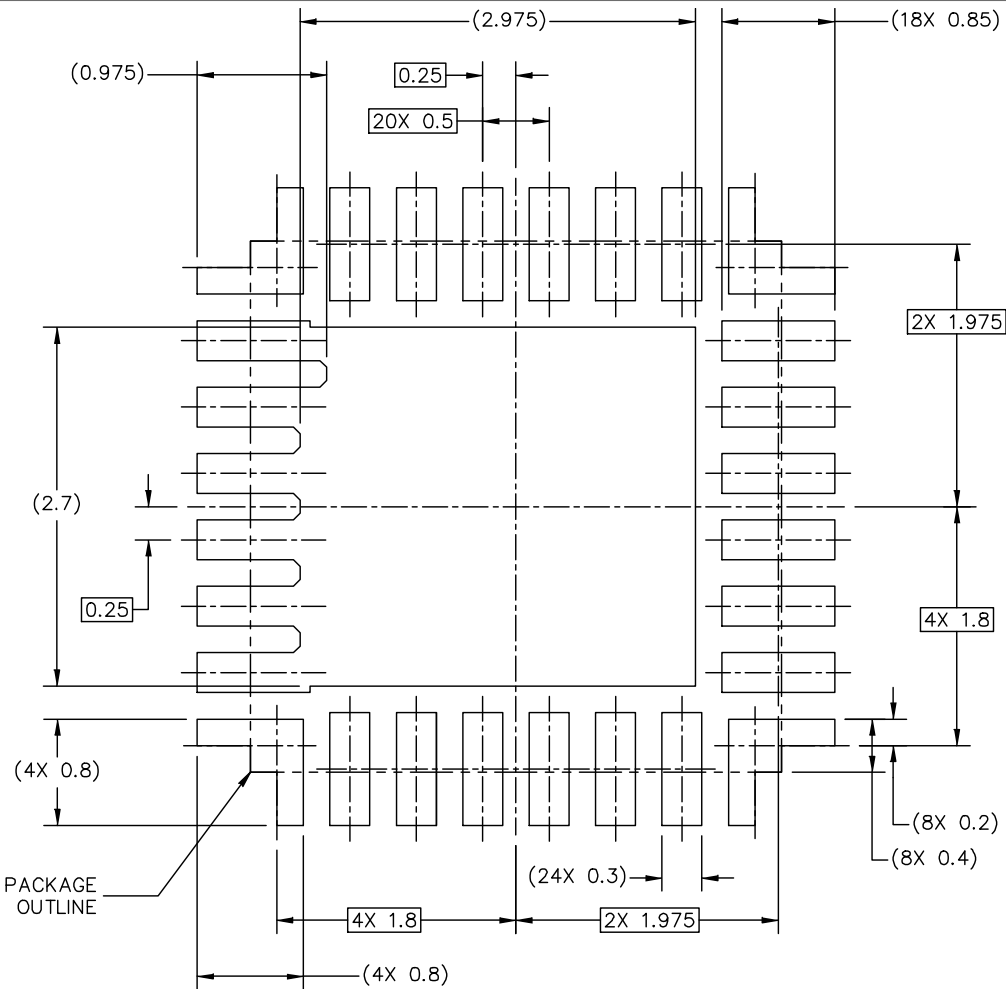
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PROCESSES AND BOARD DESIGN IN ORDER TO MEET INDIVIDUAL/SPECIFIC REQUIREMENTS.

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|--------------------------------------------------|------------------------|--------------------------------|----------------|

**Figure 10. Reflow soldering footprint part1 for HQFN24 (SOT1931-1(D))**

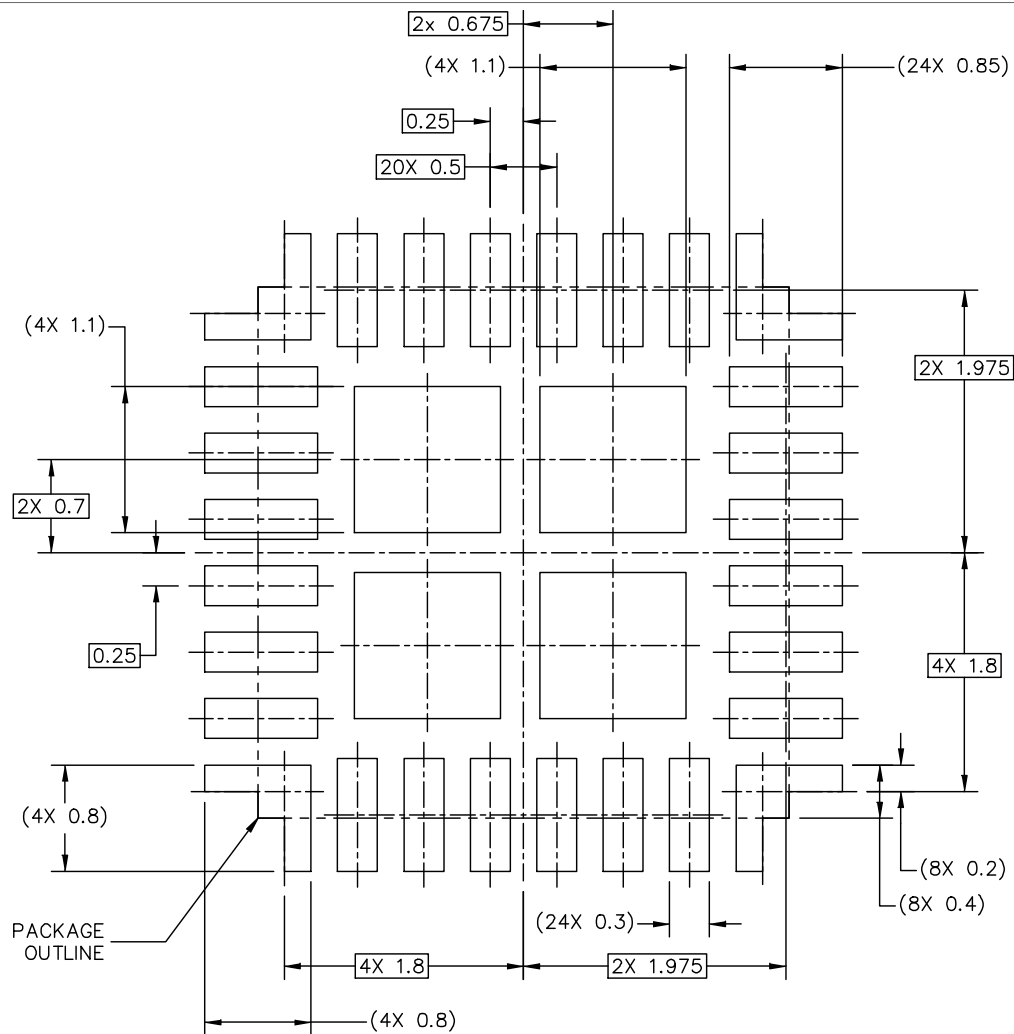


PCB DESIGN GUIDELINES – I/O PADS AND SOLDERABLE AREA

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Figure 11. Reflow soldering footprint part2 for HQFN24 (SOT1931-1(D))



RECOMMENDED STENCIL THICKNESS 0.125

PCB DESIGN GUIDELINES – SOLDER PASTE STENCIL

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|--------------------------------------------------|------------------------|--------------------------------|----------------|--|

Figure 12. Reflow soldering footprint part3 for HQFN24 (SOT1931-1(D))

- NOTES:
- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
  - 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
  - 3. PIN 1 FEATURE SHAPE, SIZE AND LOCATION MAY VARY.
  - 4. COPLANARITY APPLIES TO LEADS, DIE ATTACH FLAG AND CORNER NON-FUNCTIONAL PADS.
  - 5. ANCHORING PADS.
  - 6. STEP-CUT IS APPLIED FOR BURR REMOVAL ONLY.

|                                                  |                        |                                |                   |  |
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Figure 13. Package outline notes HQFN24 (SOT1931-1(D))

10 References

NXP reference documents

- [1] UM11227, *NTM88 family of tire pressure monitor sensors*
- [2] NXP Specification NXPOMS-1719007347-17056, *Media Stress Methodologies for Sensors*, Contact your NXP sales representative for more information
- [3] AN1902, *Assembly guidelines for QFN (quad flat no-lead) and SON (small outline no-lead) packages*

## 11 Revision history

Table 23. Revision history

| Document ID      | Release date    | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|------------------|-----------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NTM88Jxx5S v.2   | 6 June 2024     | <ul style="list-style-type: none"><li>• NTM88Jxx5S v.2 supercedes NTM88Jxx5S v.1.2.</li><li>• NTM88Jxx5S v.2 is a preliminary data sheet.</li><li>• <a href="#">Section 2</a>, revised "Six-channel, 8-, 10-, or 12-bit analog-to-digital converter (ADC10) with two external I/O inputs" to "Six-channel, 8-, 10-, or 12-bit analog-to-digital converter with two external I/O inputs".</li><li>• <a href="#">Section 5.2</a>, <a href="#">Table 3</a>, revised as follows:<ul style="list-style-type: none"><li>– RST_B: Removed "/ V<sub>PP</sub> programming voltage" from the Function and revised the first paragraph in the description.</li><li>– GND: revised the first sentence of the description.</li></ul></li><li>• <a href="#">Section 6.10.1</a>, <a href="#">Table 15</a>, revised the table adding additional rows, revising values and updating references in the notes column.</li><li>• <a href="#">Section 6.13</a>, <a href="#">Table 21</a>, added footnote to PRF2, PRF3, H2, H3, and H4 to the parameter field.</li><li>• <a href="#">Section 7.1</a>, <a href="#">Table 22</a>, removed the row A<sub>CROSS</sub> from the table.</li><li>• <a href="#">Section 7.2</a>, revised the specification and added a note.</li><li>• <a href="#">Section 10</a>, revised the NXP specification entry number and title.</li></ul> |
| NTM88Jxx5S v.1.2 | 21 July 2023    | <ul style="list-style-type: none"><li>• NTM88Jxx5S v.1.2 supercedes NTM88Jxx5S v.1.1.</li><li>• NTM88Jxx5S v.1.2 is an objective data sheet.</li><li>• <a href="#">Section 3 "Ordering information"</a>, removed the subsection titled "Hardware version numbers".</li></ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
| NTM88Jxx5S v.1.1 | 23 June 2023    | <ul style="list-style-type: none"><li>• NTM88Jxx5S v.1.1 supercedes NTM88Jxx5S v.1.</li><li>• NTM88Jxx5S v.1.1 is an objective data sheet.</li><li>• <a href="#">Table 2</a>, revised the values for Code H.</li></ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| NTM88Jxx5S v.1   | 12 October 2022 | <ul style="list-style-type: none"><li>• NTM88Jxx5S v.1 supercedes NTM88xxx5S v.1.2. This document supercedes NTM88xxx5S v.1.2 for the relevant part numbers in <a href="#">Section 3</a>, <a href="#">Table 2 "Ordering options"</a>.</li><li>• NTM88Jxx5S v.1 is an objective data sheet.</li><li>• Initial release.</li></ul>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |

Legal information

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|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
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| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

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